

TDC1011 Single Channel Ultrasonic Sensing Analog Front End (AFE) for Level Sensing, Concentration Sensing Applications

1 Features

- Measurement Range: Up to 8 ms
- Operating Current: 1.8 μ A (2 SPS)
- Transmitter Channel TX
 - Supports Single Transducer Applications
 - Programmable Excitation: 31.25 kHz to 4 MHz, Up to 31 Pulses
- Receiver Channel RX
 - STOP Cycle-to-Cycle Jitter: 50 pS_{RMS}
 - Low-Noise and Programmable Gain Amplifiers
 - Access to Signal Chain for External Filter Design
 - Programmable Threshold Comparator for Echo Qualification
 - Programmable Low Power Mode for Long TOF Measurements
- Temperature Measurement
 - Interface to Two PT1000/500 RTDs
 - RTD-to-RTD Matching Accuracy 0.02°C_{RMS}
- Operating Temperature Range: -40°C to 125°C

2 Applications

- Measurements Through Tanks of Varying Materials:
 - Fluid Level
 - Fluid Identification / Concentration

3 Description

The TDC1011 is a fully integrated analog front-end (AFE) for ultrasonic sensing measurements of liquid level, fluid identification/concentration, and proximity/distance applications common in automotive, industrial, medical, and consumer markets. When paired with an MSP430/C2000 MCU, power, wireless, and source code, TI provides the complete ultrasonic sensing solution.

TI's Ultrasonic AFE offers programmability and flexibility to accommodate a wide-range of applications and end equipment. The TDC1011 can be configured for multiple transmit pulses and frequencies, gain, and signal thresholds for use with a wide-range of transducer frequencies (31.25kHz to 4MHz) and Q-factors. Similarly, the programmability of the receive path allows ultrasonic waves to be detected over a wider range of distances/tank sizes and through various mediums.

Selecting different modes of operation, the TDC1011 can be optimized for low power consumption, making it ideal for battery powered applications. The low noise amplifiers and comparators provide extremely low jitter, enabling picosecond resolution and accuracy.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TDC1011	TSSOP (PW-28)	9.70 mm x 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

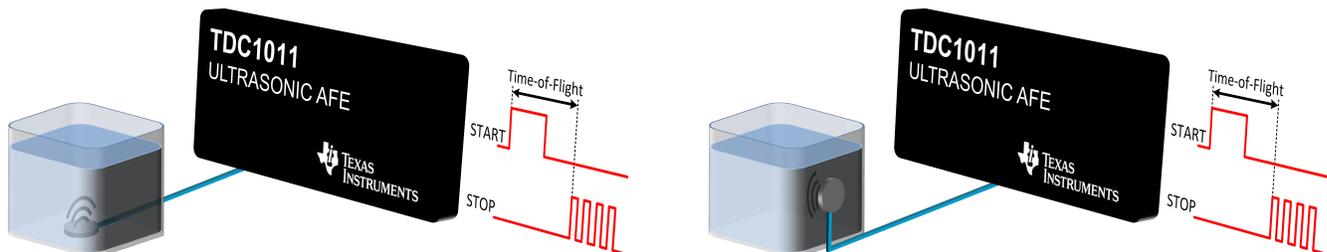


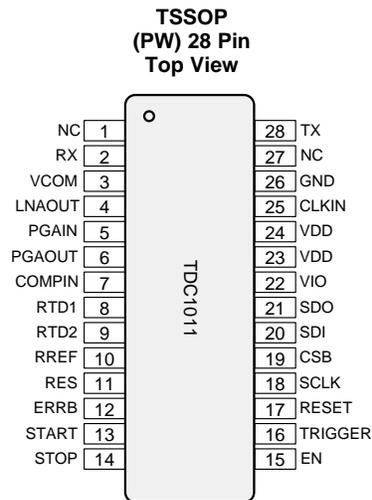
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4 Revision History

DATE	REVISION	NOTES
July 2015	*	Initial release.

5 Pin Configuration and Functions



Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
NC	1		No Connect (leave floating)
RX	2	I	Receive input
VCOM	3	P	Output common mode voltage bias
LNAOUT	4	O	Low noise amplifier output (for ac decoupling capacitor)
PGAIN	5	I	Programmable gain amplifier input
PGAOUT	6	O	Programmable gain amplifier output
COMPIN	7	I	Echo qualification and zero-crossing detector input
RTD1	8	O	Resistance temperature detector channel 1
RTD2	9	O	Resistance temperature detector channel 2
RREF	10	O	Reference resistor for temperature measurement
RES	11	I	Reserved (connect to GND)
ERRB	12	O	Error flag (open drain)
START	13	O	Start pulse output
STOP	14	O	Stop pulse output
EN	15	I	Enable (active high; when low the TDC1011 is in SLEEP mode)
TRIGGER	16	I	Trigger input
RESET	17	I	Reset (active high)
SCLK	18	I	Serial clock for the SPI interface
CSB	19	I	Chip select for the SPI interface (active low)
SDI	20	I	Serial data input for the SPI interface
SDO	21	O	Serial data output for the SPI interface
VIO	22	P	Positive I/O supply
VDD	23, 24	P	Positive supply; all VDD supply pins must be connected to the supply. Place a 100-nF bypass capacitor to ground in close proximity to the pin.
CLKIN	25	I	Clock input
GND	26	G	Negative supply
NC	27		No Connect (leave floating)
TX	28	O	Transmit output

(1) G = Ground, I = Input, O = Output, P = Power

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) ⁽¹⁾⁽²⁾

		MIN	MAX	UNIT
V _{DD}	Analog supply voltage, VDD pins	-0.3	6.0	V
V _{IO}	I/O supply voltage (V _{IO} must always be lower than or equal to V _{DD} supply)	-0.3	6.0	V
V _I	Voltage on any analog input pin ⁽³⁾	-0.3	V _{DD} + 0.3	V
V _I	Voltage on any digital input pin ⁽³⁾	-0.3	V _{IO} + 0.3	V
I _I	Input current at any pin		5	mA
T _J	Operating junction temperature	-40	125	°C
T _{stg}	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to ground, unless otherwise specified.
- (3) When the input voltage at a pin exceeds the power supplies, the current at that pin must not exceed 5 mA and the voltage (V_I) at that pin must not exceed 6.0 V.

6.2 ESD Ratings

		VALUE	UNIT	
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC A100-002 ⁽¹⁾	±2000	
		Charged-device model (CDM), per AEC Q100-011	All pins	±500
			Corner pins (1, 14, 15 and 28)	±750

- (1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{DD}	Analog supply voltage, VDD pins	2.7	5.5	V
V _{IO}	Digital supply voltage, (V _{IO} must always be lower than or equal to V _{DD} supply)	1.8	V _{DD}	V
V _I	Voltage on any analog input pin	GND	V _{DD}	V
V _I	Voltage on any digital input pin	GND	V _{IO}	V
f _{CLKIN}	Operating frequency	0.06	16	MHz
T _J	Operating junction temperature	-40	125	°C

6.4 Thermal Information ⁽¹⁾

THERMAL METRIC		TDC1011 TSSOP PW (28 PINS)	UNIT
R _{θJA}	Junction-to-ambient thermal resistance	83.5	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	29.9	
R _{θJB}	Junction-to-board thermal resistance	40.8	
ψ _{JT}	Junction-to-top characterization parameter	2.4	
ψ _{JB}	Junction-to-board characterization parameter	40.3	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics

The electrical ratings specified in this section apply to all specifications in this document, unless otherwise noted. These specifications are interpreted as conditions that do not degrade the device parametric or functional specifications for the life of the product containing it. $T_A = 25^\circ\text{C}$, $V_{DD} = V_{IO} = 3.7\text{ V}$, $V_{COM} = V_{CM} = V_{DD} / 2$, $C_{VCOM} = 10\text{ nF}$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
TRANSMITTER SIGNAL PATH (TX)							
$V_{OUT(TX)}$	Output voltage swing	$f_{out} = 1\text{ MHz}$, $R_L = 75\ \Omega$ to V_{CM}	HIGH	$V_{DD} - 0.32$			V
			LOW	0.32			V
$I_{OUT(TX)}$	Output drive current	$f_{out} = 1\text{ MHz}$, $R_L = 75\ \Omega$ to V_{CM}		22			mA_{RMS}
$f_{OUT(TX)}$	Output TX frequency	$f_{CLKIN} = 8\text{ MHz}$, divide-by-2 (programmable; see Transmitter Signal Path)		4			MHz
RECEIVER SIGNAL PATH (RX)							
Δt_{STOP}	STOP cycle-to-cycle jitter	LNA capacitive feedback, $G_{PGA} = 6\text{ dB}$, $f_{IN} = 1\text{ MHz}$, $V_{IN} = 100\text{ mV}_{PP}$, $C_{VCOM} = 1\ \mu\text{F}$ and Figure 14		50			ps_{RMS}
LNA							
G_{LNA}	LNA gain	Capacitive feedback, $C_{IN} = 300\text{ pF}$, $f_{IN} = 1\text{ MHz}$, $R_L = 100\text{ k}\Omega$ to V_{CM} , $C_{VCOM} = 1\ \mu\text{F}$		20			dB
e_{NLNA}	LNA input referred noise density	Capacitive feedback, $C_{IN} = 300\text{ pF}$, $f = 1\text{ MHz}$, $V_{DD} = 3.1\text{ V}$, $V_{IN} = V_{CM}$, $R_L = \infty$, $C_{VCOM} = 1\ \mu\text{F}$		2			$\text{nV}/\sqrt{\text{Hz}}$
$V_{IN(LNA)}$	Input voltage range	Resistive feedback, $R_L = 1\text{ k}\Omega$ to V_{CM} , $C_{VCOM} = 1\ \mu\text{F}$	HIGH	$V_{CM} + (V_{CM} - 0.24) / (G_{LNA})$			V
			LOW	$V_{CM} - (V_{CM} - 0.24) / (G_{LNA})$			V
$V_{OUT(LNA)}$	Output voltage range	Resistive feedback, $R_L = 1\text{ k}\Omega$ to V_{CM} , $C_{VCOM} = 1\ \mu\text{F}$	HIGH	$V_{DD} - 0.24$			V
			LOW	$\text{GND} + 0.24$			V
SR_{LNA}	Slew rate ⁽¹⁾	Resistive feedback, $R_L = 1\text{ k}\Omega$ to V_{CM} , 100mV step, $C_{VCOM} = 1\ \mu\text{F}$		9			$\text{V}/\mu\text{s}$
BW_{LNA}	-3-dB bandwidth	Capacitive feedback, $C_{IN} = 300\text{ pF}$, $R_L = 100\text{ k}\Omega$ to V_{CM} , $C_{VCOM} = 1\ \mu\text{F}$		5			MHz
$V_{OS(LNA)}$	LNA input offset voltage	Resistive mode, $V_{IN} = V_{CM}$, $R_L = \infty$		± 320			μV
VCOM							
V_{COM}	VCOM output voltage	$C_{VCOM} = 1\ \mu\text{F}$		V_{CM}			V
	VCOM output error			0.5%			
PGA							
$V_{IN(PGA)}$	PGA input range	$R_L = 100\text{ k}\Omega$ to V_{CM} , $C_L = 10\text{ pF}$ to GND	HIGH	$V_{CM} + (V_{CM} - 0.06) / (G_{PGA})$			V
			LOW	$V_{CM} - (V_{CM} - 0.06) / (G_{PGA})$			V
G_{PGAMIN}	PGA min gain	DC, $R_L = \infty$, $C_L = 10\text{ pF}$		0			dB
G_{PGAMAX}	PGA max gain			21			dB
ΔG_{PGA}	PGA gain step size			3			dB
$G_E(PGA)$	PGA gain error	DC, $G_{PGA} = 0\text{ dB}$, $R_L = \infty$, $C_L = 10\text{ pF}$		5%			
TCG_{PGA}	PGA gain temperature coefficient	DC, $G_{PGA} = 0\text{ dB}$, $R_L = \infty$, $C_L = 10\text{ pF}$		170			$\text{ppm}/^\circ\text{C}$
e_{NPGA}	PGA input referred noise density	$G_{PGA} = 21\text{ dB}$, $f = 1\text{ MHz}$, $V_{DD} = 3.1\text{ V}$, $V_{IN} = V_{CM}$, $R_L = \infty$, $C_{VCOM} = 1\ \mu\text{F}$		3.1			$\text{nV}/\sqrt{\text{Hz}}$
$V_{OUT(PGA)}$	Output range	$R_L = 100\text{ k}\Omega$ to V_{CM} , $C_L = 10\text{ pF}$ to GND	HIGH	$V_{DD} - 0.06$			V
			LOW	60			mV
BW_{PGA}	-3-dB bandwidth	$G_{PGA} = 21\text{ dB}$, $R_L = 100\text{ k}\Omega$ to V_{CM} , $C_L = 10\text{ pF}$, $C_{VCOM} = 1\ \mu\text{F}$		5			MHz
SR_{PGA}	Slew rate ⁽¹⁾	$G_{PGA} = 21\text{ dB}$, $R_L = 100\text{ k}\Omega$ to V_{CM} , $C_L = 10\text{ pF}$, $C_{VCOM} = 1\ \mu\text{F}$		12.5			$\text{V}/\mu\text{s}$

(1) The slew rate is measured from 10% to 90% and is represented by the average of the rising and falling slew rates.

Electrical Characteristics (continued)

The electrical ratings specified in this section apply to all specifications in this document, unless otherwise noted. These specifications are interpreted as conditions that do not degrade the device parametric or functional specifications for the life of the product containing it. $T_A = 25^\circ\text{C}$, $V_{DD} = V_{IO} = 3.7\text{ V}$, $V_{COM} = V_{CM} = V_{DD} / 2$, $C_{VCOM} = 10\text{ nF}$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
ZERO CROSS COMPARATOR						
$V_{OS(Comp)}$	Input offset voltage ⁽²⁾	Referred to V_{COM}		±115		μV
en_{COMP}	Zero crossing comparator input referred noise ⁽²⁾	1 MHz		5		nV/√Hz
$HYST_{COMP}$	Hysteresis ⁽²⁾	Referred to V_{COM}		-10		mV
THRESHOLD DETECTOR						
V_{THDET}	Threshold level	ECHO_QUAL_THLD = 0h, V_{COM} referred		-35		mV
		ECHO_QUAL_THLD = 7h, V_{COM} referred		-1.5		V
TEMPERATURE SENSOR INTERFACE⁽³⁾						
T_{ERROR}	Temperature measurement accuracy	$R_{REF} = 1\text{ k}\Omega$, PT1000 range: -40 to 125°C ⁽⁴⁾		1		°C
		$R_{REF} = 1\text{ k}\Omega$, PT1000 range: -15°C to 85°C ⁽⁴⁾		0.5		°C
	Relative accuracy	$R_{REF} = 1\text{ k}\Omega$, $R_{RTD1} = R_{RTD2} = 1.1\text{ k}\Omega$		0.02		°C _{RMS}
TG_E	Gain error			5.8		m°C/°C
POWER SUPPLY						
I_{DD}	VDD supply current	Sleep (EN = CLKIN = TRIGGER = low)		0.61		μA
		Continuous receive mode, LNA and PGA bypassed		2.8	3	mA
		Continuous receive mode, LNA and PGA active		6.2	7.5	mA
		Temp. measurement only (PT1000 mode) ⁽⁵⁾		370	400	μA
		Temp. measurement (PT500 mode) ⁽⁶⁾		500	540	μA
I_{IO}	VIO supply sleep current ⁽²⁾	Sleep (EN = CLKIN = TRIGGER = low)		2		nA
DIGITAL INPUT/OUTPUT CHARACTERISTICS						
V_{IL}	Input logic low threshold			$0.2 \times V_{IO}$		V
V_{IH}	Input logic high threshold		$0.8 \times V_{IO}$			V
V_{OL}	Output logic low threshold	SDO pin, 100-μA current			0.2	V
		SDO pin, 1.85-mA current			0.4	V
		START and STOP pins, 100-μA current			0.5	V
		START and STOP pins, 1.85-mA current			0.6	V
		ERRB pin, 100-μA current			0.2	V
		ERRB pin, 1.85-mA current			0.4	V
V_{OH}	Output logic high threshold	SDO pin, 100-μA current	$V_{IO} - 0.2$			V
		SDO pin, 1.85-mA current	$V_{IO} - 0.6$			V
		START and STOP pins, 100-μA current	$V_{IO} - 0.5$			V
		START and STOP pins, 1.85-mA current	$V_{IO} - 0.6$			V
		ERRB pin, 0-μA current	$V_{IO} - 0.2$			V
I_{OMAX}	Maximum output current for SDO, START and STOP			1.85		mA

(2) Specified by design.

(3) With ideal external components. For more detail see *Temp Sensor Measurement* section.

(4) PT1000 RTD approximate resistance: $800\ \Omega \equiv -52^\circ\text{C}$, $931\ \Omega \equiv -18^\circ\text{C}$, $1.10\text{ k}\Omega \equiv 26^\circ\text{C}$, $1.33\text{ k}\Omega \equiv 86^\circ\text{C}$ and $1.48\text{ k}\Omega \equiv 125^\circ\text{C}$.

(5) Specified currents include 120μA which flows through the RTD sensor in PT1000 mode (TEMP_RTD_SEL = 0).

(6) Specified currents include 240μA which flows through the RTD sensor in PT500 mode (TEMP_RTD_SEL = 1).

6.6 Timing Requirements

 $T_A = 25^\circ\text{C}$, $V_{DD} = V_{IO} = 3.7\text{ V}$ and $f_{SCLK} = 1\text{ MHz}$ (unless otherwise noted).

		MIN	NOM	MAX	UNIT
f_{SCLK}	Serial clock frequency			26	MHz
t_1	High period, SCLK	16			ns
t_2	Low period, SCLK	16			ns
t_3	Set-up time, nCS to SCLK	10			ns
t_4	Set-up time, SDI to SCLK	12			ns
t_5	Hold time, SCLK to SDI	12			ns
t_6	SCLK transition to SDO valid time	16			ns
t_7	Hold time, SCLK transition to nCS rising edge	10			ns
t_8	nCS inactive	17			ns
t_9	Hold time, SCLK transition to nCS falling edge	10			ns
t_r / t_f	Signal rise and fall times ⁽¹⁾		1.8		ns

(1) The slew rate is measured from 10% to 90% and is represented by the average of the rising and falling slew rates.

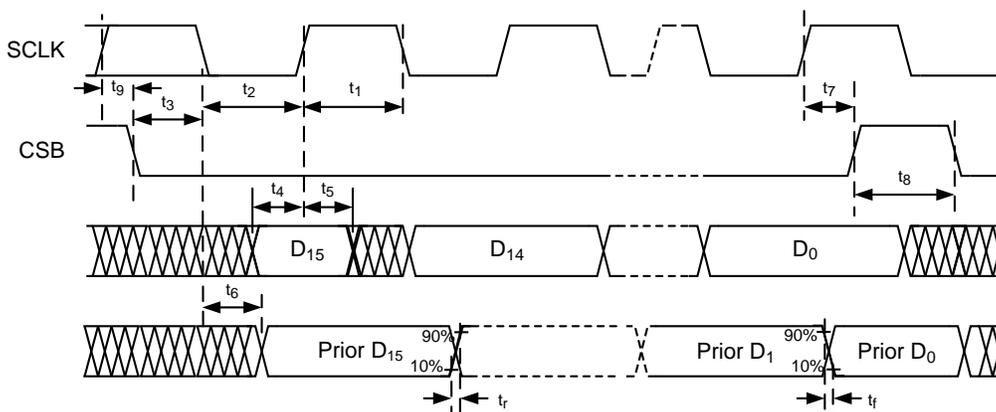


Figure 1. SPI Timing Diagram

6.7 Switching Characteristics

 $T_A = 25^\circ\text{C}$, $V_{DD} = V_{IO} = 3.7\text{ V}$, $f_{CLKIN} = 8\text{ MHz}$.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
START, STOP, ENABLE, RESET, CLOCKIN, TRIGGER, ERR					
PW _{START}	Pulse width for START signal	TX_FREQ_DIV = 2h, NUM_TX = 1	1		μs
		TX_FREQ_DIV = 2h, NUM_TX = 2	2		μs
		TX_FREQ_DIV = 2h, NUM_TX ≥ 3	3		μs
t_r / t_f _{START}	Rise/fall time for START signal	20% to 80%, 20-pF load	0.25		ns
t_r / t_f _{STOP}	Rise/fall time for STOP signal	20% to 80%, 20-pF load	0.25		ns
f_{CLKIN}	Maximum CLKIN input frequency		16		MHz
t_r / t_f _{CLKIN}	CLKIN input rise/fall time ⁽¹⁾	20% to 80%	10		ns
t_r / t_f _{TRIG}	TRIGGER input rise/fall time ⁽¹⁾	20% to 80%	10		ns
t_{EN_TRIG}	Enable to trigger wait time ⁽¹⁾		50		ns
t_{RES_TRIG}	Reset to trigger wait time ⁽¹⁾	TX_FREQ_DIV = 2h (see TX/RX Measurement Sequencing and Timing)	3.05		μs

(1) Specified by design.

6.8 Typical Characteristics

At $T_A = 25^\circ\text{C}$, unless otherwise noted.

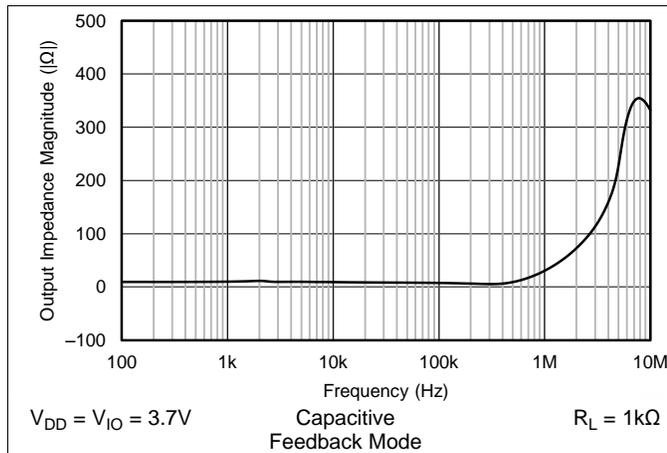


Figure 2. LNA Z_{OUT} vs Frequency

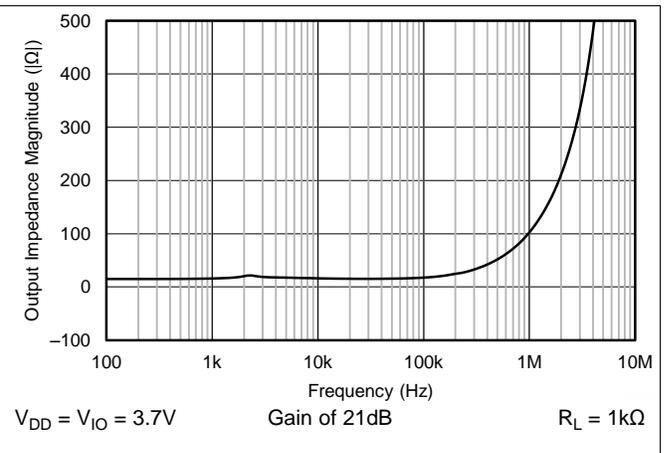


Figure 3. PGA Z_{OUT} vs Frequency

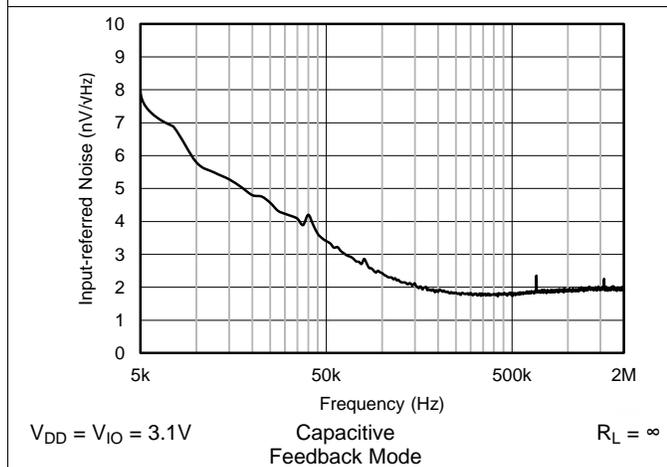


Figure 4. LNA Input-referred Noise vs Frequency

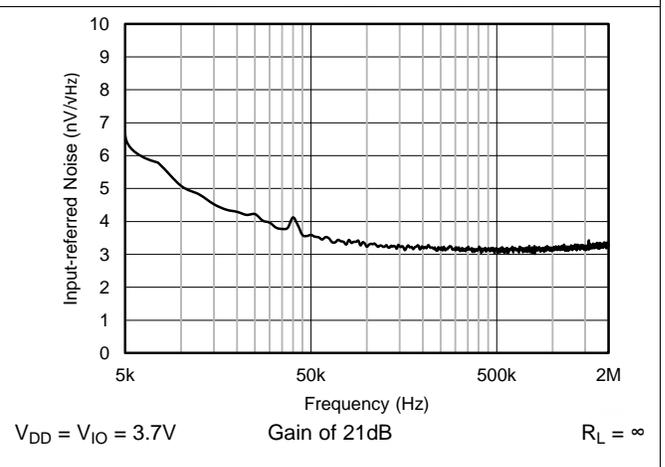


Figure 5. PGA Input-referred Noise vs Frequency

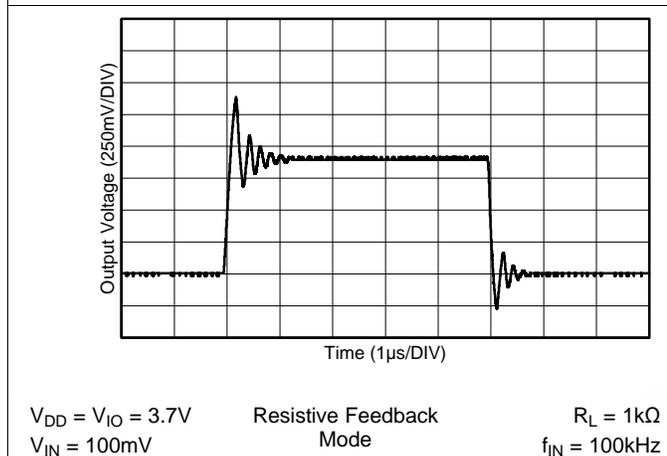


Figure 6. LNA Response

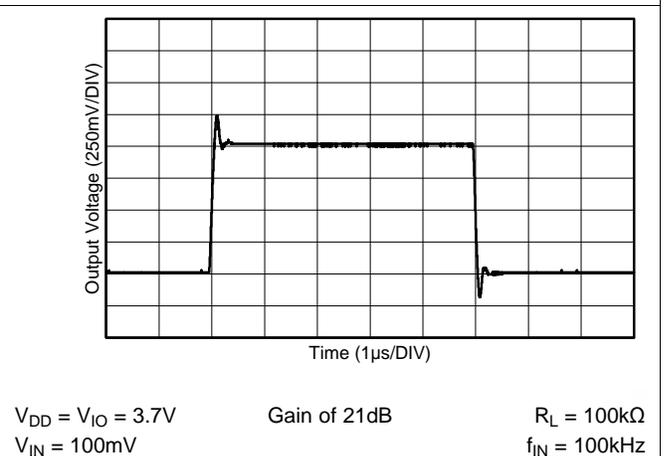
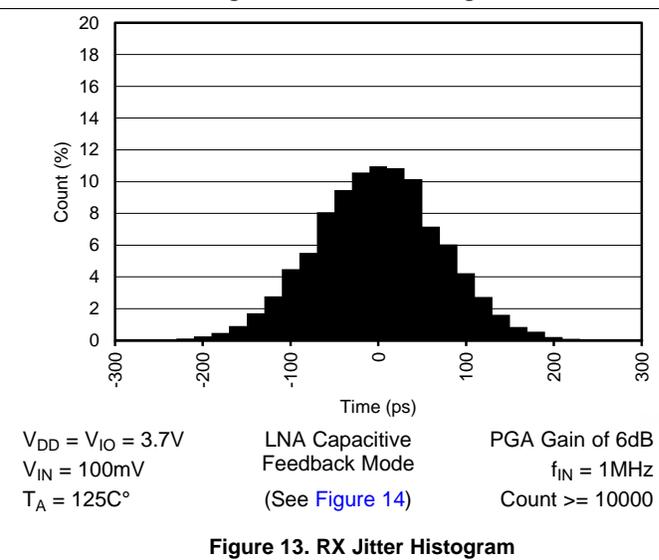
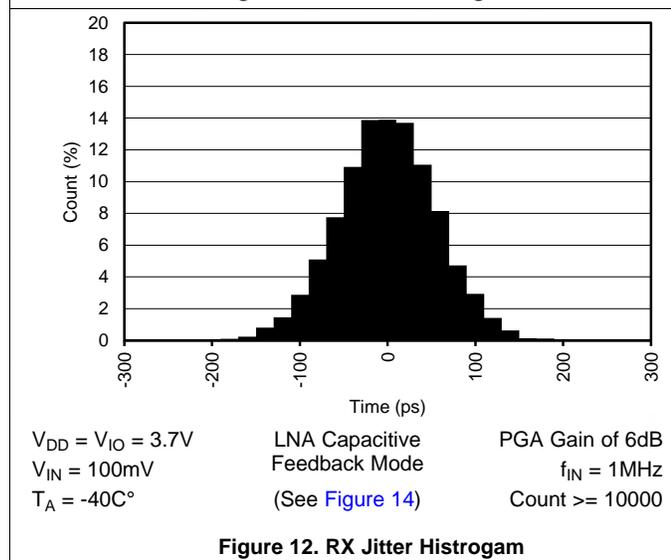
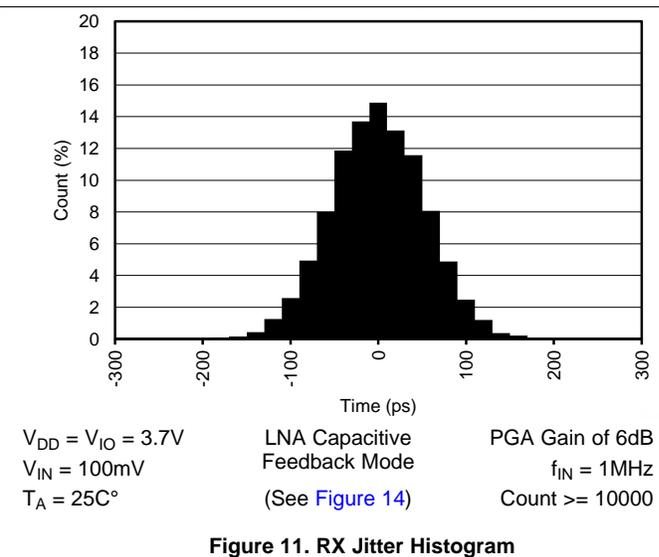
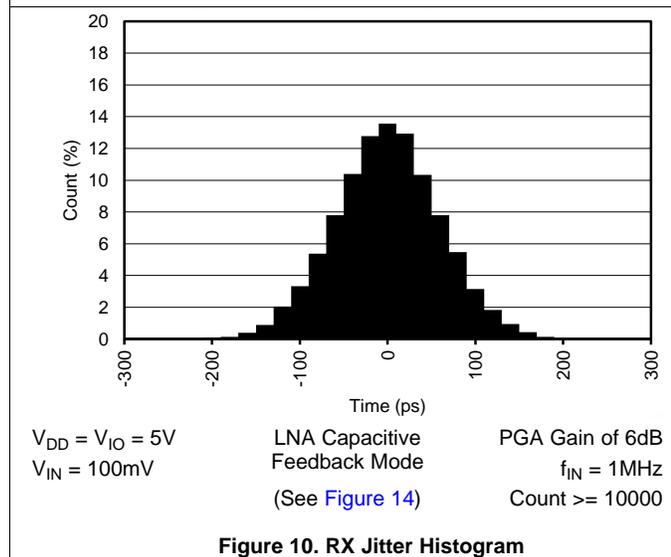
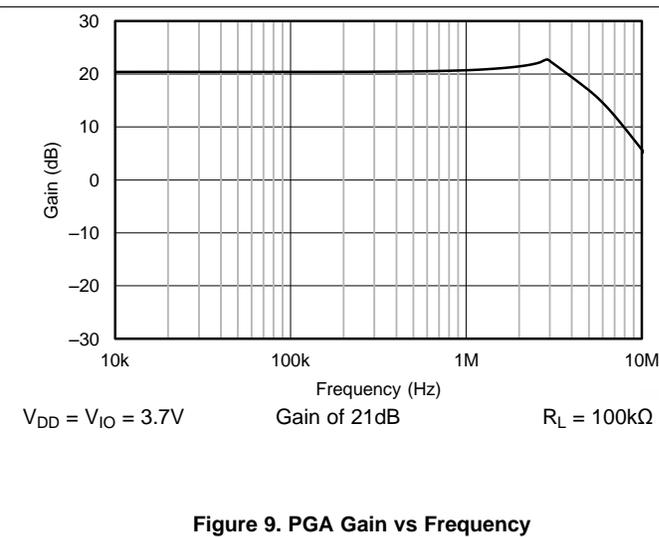
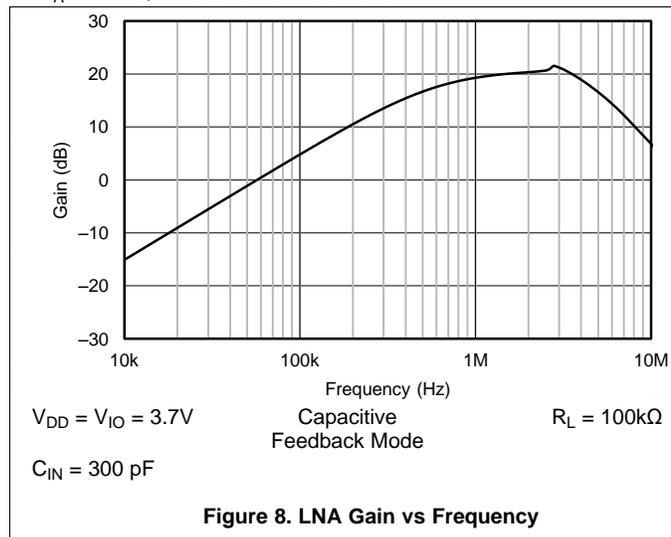


Figure 7. PGA Response

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, unless otherwise noted.



7 Parameter Measurement Information

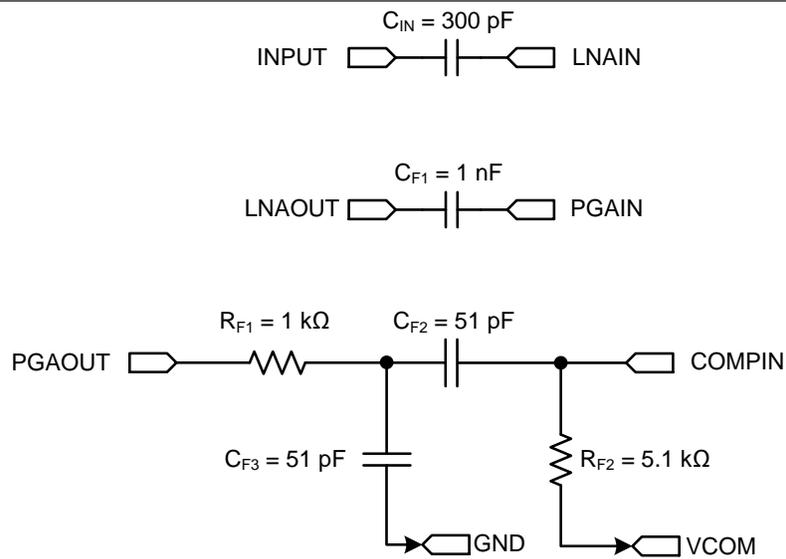


Figure 14. External Circuits for Jitter Measurement

Feature Description (continued)

8.3.3 Low Noise Amplifier (LNA)

The LNA in the TDC1011's front-end limits the input-referred noise and ensures timing accuracy for the generated STOP pulses. The LNA is an inverting amplifier designed for a closed-loop gain of 20 dB with the aid of an external input capacitor or resistor, and it can be programmed for two feedback configurations. The band-pass configuration, referred to as capacitive feedback mode, must be combined with an input capacitor. The low-pass configuration, referred to as resistive feedback mode, must be combined with an input resistor. The recommended values for the input components are 300 pF and 900 Ω respectively.

The LNA can be configured in capacitive feedback mode for transducers with resonant frequencies in the order of a couple of MHz. This is done by clearing the *LNA_FB* bit in the *TOF_1* register to 0. As shown in Figure 16, the external capacitor, C_{IN} , should be placed between the transducer and the input pin. This provides an in-band gain of C_{IN}/C_F , where C_F is the on-chip 30-pF feedback capacitor. Provided that $C_{IN} = 300$ pF, the in-band gain of the LNA circuit is:

$$\text{Gain}_{\text{in-band}} = \frac{C_{IN}}{C_F} = \frac{300 \text{ pF}}{30 \text{ pF}} = 10 \quad (1)$$

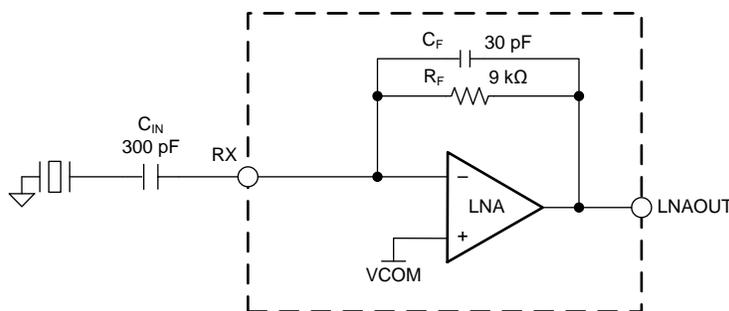


Figure 16. LNA Capacitive Feedback Configuration

The capacitive feedback configuration of the LNA has a band-pass frequency response. The high-pass corner frequency is set by the internal feedback components R_F (9 kΩ) and C_F (30 pF), and is approximately 590 kHz. The in-band gain is set by the capacitor ratio and the LNA's 50-MHz gain-bandwidth product sets the low-pass corner of the frequency response. For example, an in-band gain of 10 results in a bandpass response between 590 kHz and 5 MHz.

The LNA can be configured in resistive feedback mode for transducers with resonant frequencies in the order of a couple of hundreds of kHz. This is done by setting the *LNA_FB* bit in the *TOF_1* register to 1. In this configuration, the internal feedback capacitor C_F is disconnected (see Figure 17), and the DC gain of the LNA circuit is determined by the ratio between the internal feedback resistor R_F (9 kΩ) and an external resistor R_{IN} . For $R_{IN} = 900$ Ω, the gain of the circuit is 10.

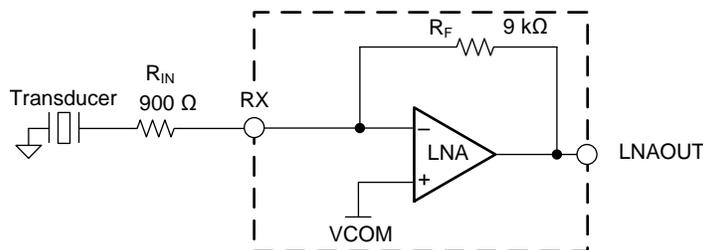


Figure 17. LNA Resistive Feedback Configuration

The LNA can be bypassed and disabled by writing a 1 to the *LNA_CTRL* bit in the *TOF_1* register.

Feature Description (continued)

8.3.4 Programmable Gain Amplifier (PGA)

The PGA, shown in [Figure 18](#), is an inverting amplifier with an input resistance of $R_{IN} = 500 \Omega$ and a programmable feedback resistor R_{FB} that can be programmed to set a 0-dB to 21-dB gain in 3-dB steps. This can be done by programming the *PGA_GAIN* field in the *TOF_1* register. The bandwidth of the PGA is scaled based on its programmed gain. The typical bandwidth of the PGA with a 100-k Ω load to VCM and a 10-pF capacitor to ground are listed in [Table 1](#).

Table 1. Typical PGA Bandwidth

PGA_GAIN (Hex)	Gain (dB)	Bandwidth (MHz)
0h	0	19.0
1h	3	16.8
2h	6	14.4
3h	9	12.3
4h	12	10.0
5h	15	8.2
6h	18	6.6
7h	21	5.0

The PGA can be bypassed and disabled by writing a 1 to the *PGA_CTRL* bit in the *TOF_1* register. The output of the PGA should not be loaded directly with capacitances greater than 10 pF.

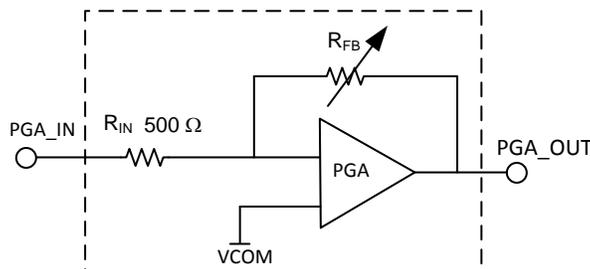


Figure 18. TDC1011 Programmable Gain Amplifier

8.3.5 Receiver Filters

It is recommended to place two filters in the RX path to minimize the receive path noise and obtain maximum timing accuracy. As shown in [Figure 19](#), one filter is placed between the LNAOUT and the PGAIN pins, and another filter is placed between the PGAOUT and the COMPIN pins.

With an in-band gain of 10, the LNA has a bandwidth of 5 MHz. For most applications, a low-pass filter between the LNAOUT and PGAIN pins is sufficient.

As shown in [Figure 19](#), the second filter stage can use a cascade of a low-pass filter (R_{F1} and C_{F3}) followed by a high-pass filter (C_{F2} and R_{F2}) referenced to VCOM. Design of the filter is straightforward. The R_{F1} and C_{F2} can be chosen first. A reasonable set of values for R_{F1} and C_{F2} could be: $R_{F1} = 1 \text{ k}\Omega \pm 10\%$ and $C_{F2} = 50\text{pF} \pm 10\%$. Given the center frequency of interest to be f_C and the filter bandwidth to be f_B , the value of C_{F3} can be calculated as:

$$C_{F3} = \frac{1}{2\pi R_{F1}(f_C + f_B)} \tag{2}$$

R_{F2} and C_{F2} determine the high-pass corner of the filter. R_{F2} should be referenced to VCOM to maintain the DC bias level at the comparator input during the echo receive time. For values of R_{F2} larger than R_{F1} , there will be limited loading effect from the high-pass filter to the low-pass filter resulting in more accurate corner frequencies. The chosen values shown in the figure below result in a high-pass corner frequency of about 600 kHz and a low-pass corner frequency of about 3 MHz.

More complex filters can be used; external gain is acceptable if the signal amplitude is too low. If the pass-band of the filter is wider than an octave, it is recommended to use a filter design which has linear group delay.

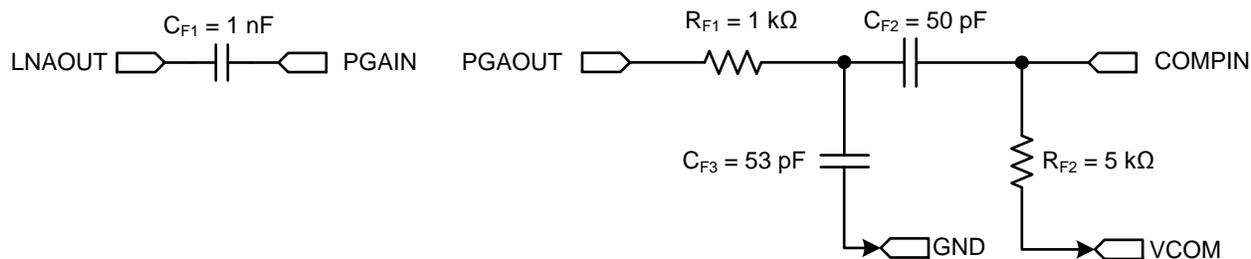


Figure 19. Filter for a 1-MHz Operation

8.3.6 Comparators for STOP Pulse Generation

The STOP pulse generation block of the TDC1011 contains two auto-zeroed comparators (a zero-cross detect and a threshold-detect comparator), a threshold setting DAC, and an event manager.

Comparator auto-zero periods occur at the beginning of every TOF receive cycle. During these periods, the comparator's input offset is stored in an internal 2.5-pF capacitor, and it is subtracted from the input signal during the echo processing phase. The duration of auto-zero period is configured with the *AUTOZERO_PERIOD* field located in the *CLOCK_RATE* register.

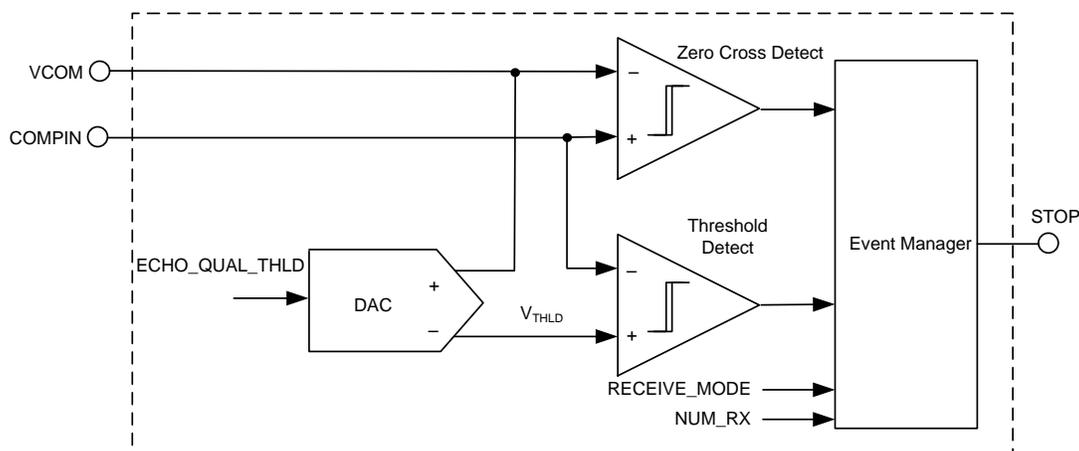


Figure 20. STOP Pulse Generation Circuit

8.3.6.1 Threshold Detector and DAC

The threshold detect comparator in Figure 20 compares the echo amplitude with a programmable threshold level (V_{THLD}) controlled by a DAC. The DAC voltage is set by the *ECHO_QUAL_THLD* field in register *CONFIG_3* and provides 8 programmable threshold levels, V_{THLD} . The typical levels are summarized in Table 2:

Table 2. Echo Qualification Threshold Levels

ECHO_QUAL_THLD	0h	1h	2h	3h	4h	5h	6h	7h
Typical V_{THLD} (mV)	-35	-50	-75	-125	-220	-410	-775	-1500

8.3.6.2 Zero-cross Detect Comparator

The zero-cross detect comparator compares the amplified echo signal at COMPIN with its reference voltage, which is V_{COM} . As shown in Figure 21, the comparator produces a low-to-high transition when the amplitude of the echo signal rises above V_{COM} . The comparator produces a high-to-low transition when the echo amplitude falls below $V_{COM} - V_{HYST}$. The built-in negative-sided hysteresis of 10 mV in reference to V_{COM} ensures accurate zero-cross time instances associated with the rising edges of the echo signal and immunity of the comparator output to noise.

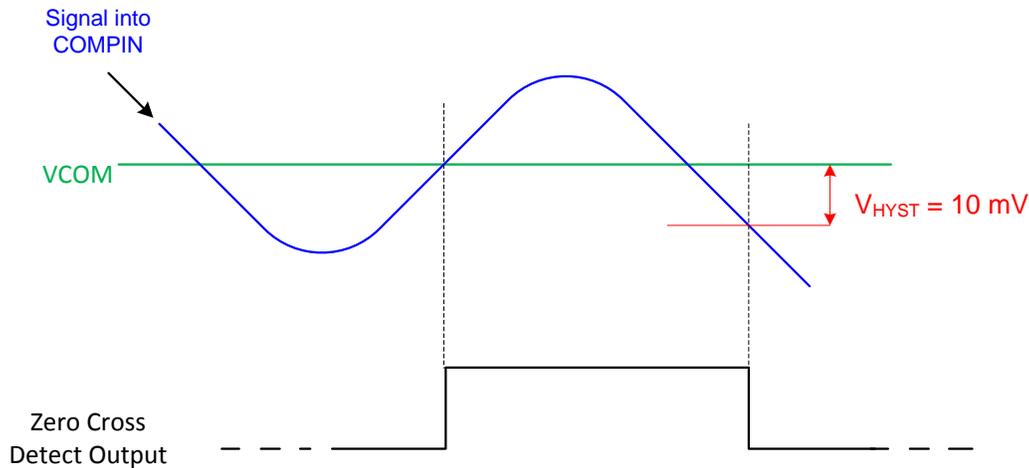


Figure 21. Zero-Cross Detector Output Signal

The output of the zero-cross detect comparator is passed to the event manager, where depending on the decision of the threshold-detect comparator.

8.3.6.3 Event Manager

The event manager is a digital state machine in the STOP pulse generation circuit of the TDC1011. The event manager controls the maximum number of STOP pulses to generate on the STOP pin and the receive mode for the STOP pulse generation. The number of STOP pulses is configured in the `NUM_RX` field in the `CONFIG_1` register. The receive mode is selected in the `RECEIVE_MODE` bit of the `CONFIG_4` register. See sections [Single Echo Receive Mode](#) and [Multiple Echo Receive Mode](#) for details about the receiver modes of the TDC1011.

An example for `NUM_RX = 2h` and `RECEIVE_MODE = 0` is shown in [Figure 22](#). When the echo signal amplitude exceeds values smaller than V_{THLD} , the threshold detect comparator indicates to the event manager to qualify the next zero-cross event as valid. When the qualified zero-cross is detected by the zero-cross detect comparator, the event manager passes the pulse to the STOP pin until the number of receive events programmed in `NUM_RX` is reached.

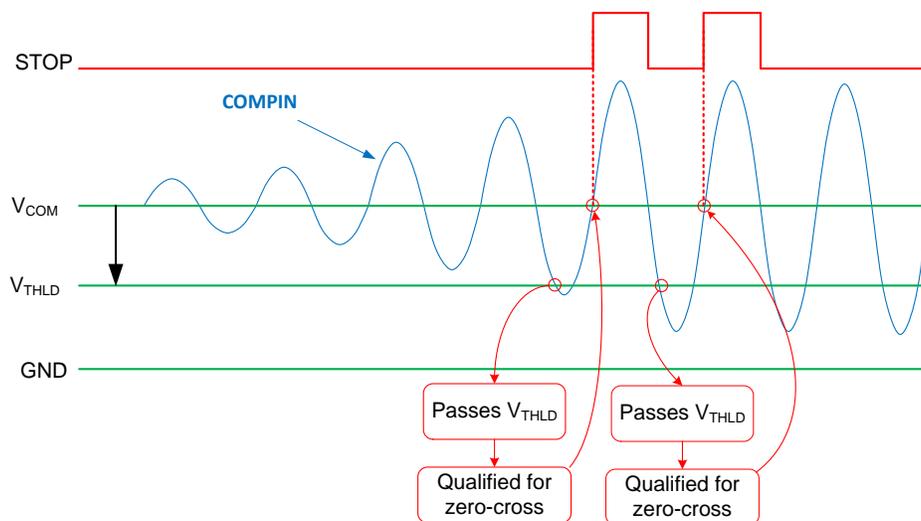


Figure 22. Signal Qualification, Zero-cross Detection and STOP Pulse Generation

8.3.7 Common-mode Buffer (VCOM)

The output of the internal common-mode buffer is present at the VCOM pin. This pin should be bypassed to ground with a low-leakage 10-nF capacitor and it should not be loaded with more than 20 μ A. The common-mode buffer can be disabled with the *VCOM_SEL* bit in the *CONFIG_2* register. If disabled, an external reference voltage must be applied to the VCOM pin.

During a time-of-flight measurement, the common-mode reference will take approximately 16 μ s to settle if starting from zero initial conditions. Using a larger capacitor will increase the settling time of the internal common-mode reference. The implications of a larger VCOM capacitor are further explored in the *Common-mode Reference Settling Time* section.

8.3.8 Temperature Sensor

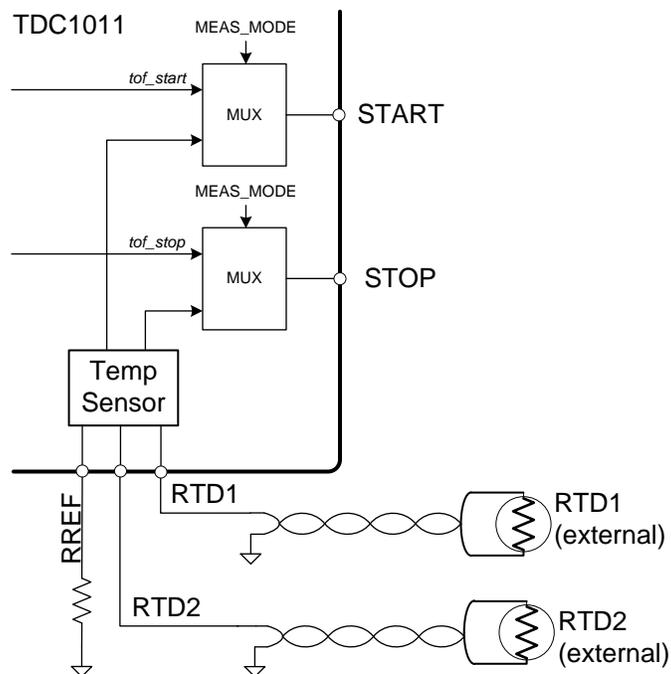


Figure 23. Temperature Sensor Measurement

Accurate measurements of level, and concentration may require compensation for the temperature dependency of the speed of sound in the medium. The TDC1011 provides two temperature sensor connections, allowing to measure up to two locations with RTDs, as shown in Figure 23.

The temperature sensor block supports PT1000 or PT500 sensors. The type of RTD used must be selected in the *TEMP_RTD_SEL* bit of the *CONFIG_3* register. The system requires a temperature-stable external reference resistor (R_{REF}). If the RTD type is PT500, then R_{REF} should be 500 Ω . If the RTD type is PT1000, then R_{REF} should be 1 k Ω . The reference resistor needs to have either a low temperature coefficient or be calibrated for temperature shift.

The logic timing in a temperature measurement is controlled by the *TEMP_CLK_DIV* bit in the *CONFIG_3* register. As shown in Figure 24, the external clock can be divided by 8 or by the value resulting from the *TX_FREQ_DIV* field configuration in the *CONFIG_0* register. It is recommended to operate the temperature measurement block at frequencies of 1 MHz or less.

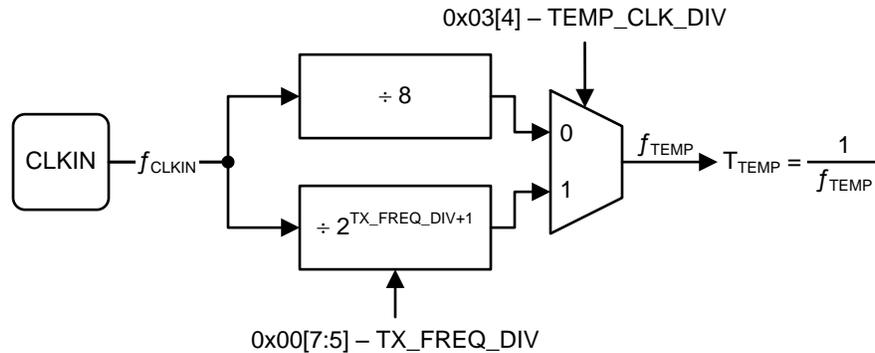


Figure 24. Timing Source for the Temperature Measurement

See the *TDC1011 Temperature Sensing Interface* application note listed in the [Temperature Measurement with Multiple RTDs](#) section for details about artifacts in the temperature measurement and how to manage them.

8.3.8.1 Temperature Measurement with Multiple RTDs

The temperature measurement mode is selected by setting the MEAS_MODE bit in the [CONFIG_2](#) register to 1. A temperature measurement is started by sending a trigger pulse. After the temperature measurement is complete, the TDC1011 returns to SLEEP mode. To return to TOF measurement mode, reset the MEAS_MODE bit to 0.

The temperature sensor measurement can be performed without the need of an external ADC. The temperature sensor block operates by converting the resistance of a reference, R_{REF} , and up to two RTDs into a series of START and STOP pulses. The interval between the pulses is proportional to the measured resistance, and therefore, the temperature. As shown in [Figure 25](#), the TDC1011 performs three measurements per trigger event and generates the corresponding pulses on the START and STOP pins.

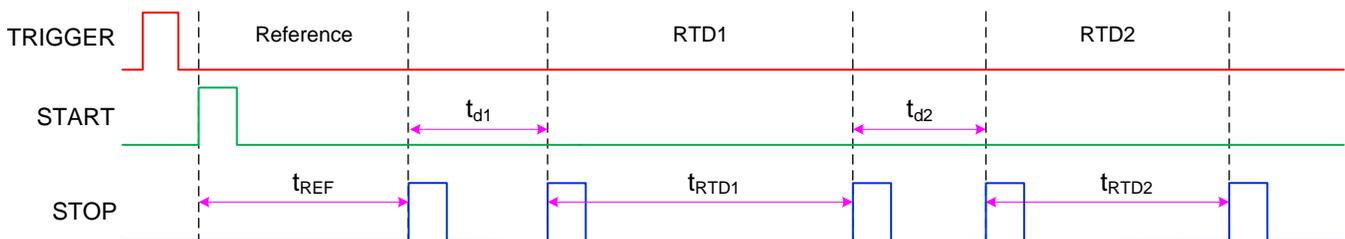


Figure 25. Temperature Measurement Output Timing

The resistance of RTD1 and RTD2 can be calculated from the time intervals in [Figure 25](#) as follows:

$$R_{RTDx} = R_{REF} \times \frac{t_{REF}}{t_{RTDx}} \quad (3)$$

With a 1-k Ω reference resistor, the t_{REF} interval is approximately 200 μ s. The following intervals, t_{RTD1} and t_{RTD2} , will depend on the resistance of the RTDs. The time delay between measurements, t_{d1} and t_{d2} , can be approximated as follows:

$$t_{d1} = (51 \times T_{TEMP}) + (t_{RTD1} \times 0.55) \quad (4)$$

$$t_{d2} = (51 \times T_{TEMP}) + (t_{RTD2} \times 0.55) \quad (5)$$

For example, two PT1000 sensors at 0 $^{\circ}$ C will have an approximate resistance of 1 k Ω ; the same as the reference resistor in this example. Given an external 8-MHz clock and the default temperature clock divide-by-8 from the *TEMP_CLK_DIV* bit, the overall measurement time between the START pulse and the last STOP pulse is approximately 922 μ s.

8.3.8.2 Temperature Measurement with a Single RTD

The temperature sensing block can be configured to measure a single RTD by setting the *TEMP_MODE* bit in register *CONFIG_3* to 1. When the temperature measurement runs in PT1000 mode (*TEMP_RTD_SEL* = 0), the first interval corresponds to R_{REF} , the second interval is a redundant measurement on R_{REF} and should be neglected, and the third interval corresponds to RTD1. This operation is represented in Figure 26.

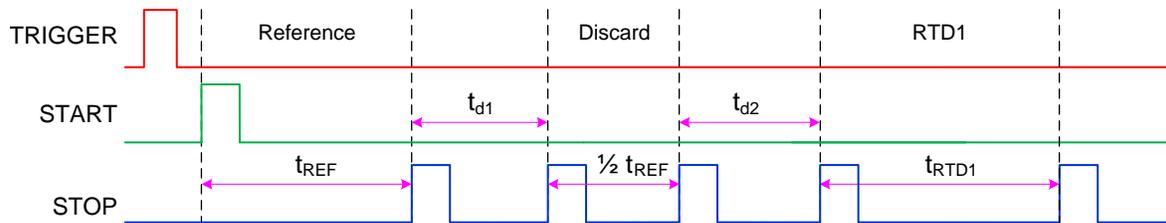


Figure 26. Temperature Measurement with a Single PT1000

The resistance of RTD1 can be calculated using Equation 3. The time delay between measurements can be approximated using Equation 4 and Equation 5, with the exception that in this case, t_{d1} is a function of $\frac{1}{2} t_{REF}$ and t_{d2} is a function of t_{RTD1} .

If the temperature measurement runs in PT500 mode (*TEMP_RTD_SEL* = 1), the first interval is a redundant measurement on R_{REF} and should be neglected, the second interval corresponds to R_{REF} , and the third interval corresponds to RTD1. This operation is represented in Figure 27.

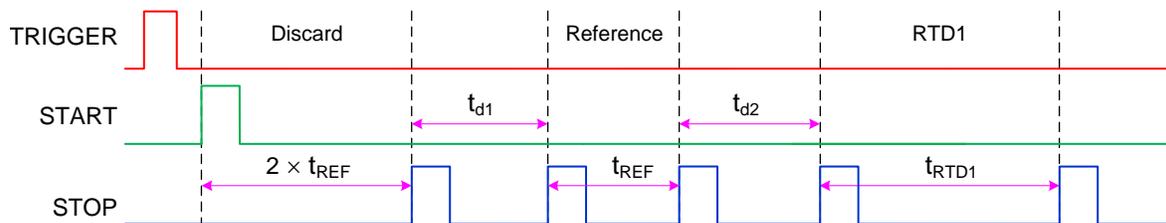


Figure 27. Temperature Measurement with a Single PT500

The resistance of RTD1 can be calculated using Equation 3. The time delay between measurements can be approximated using Equation 4 and Equation 5, with the exception that in this case, t_{d1} is a function of t_{REF} and t_{d2} is a function of t_{RTD1} .

8.4 Device Function Description

8.4.1 Time-of-Flight Measurement Mode

The TOF measurement mode is selected by setting the *MEAS_MODE* bit in the *CONFIG_2* register to 0.

8.4.1.1 Liquid Level or Fluid Identification

The TDC1011 performs a single TOF measurement after receiving a trigger signal and returns to the SLEEP mode when the measurement is complete.

8.4.2 State Machine

A state machine in the TDC1011 manages the operation of the various measurement modes (see Figure 28). At power-on, the state machine is reset and most blocks are disabled. After the power-on sequence is complete, the device goes into SLEEP mode if the EN pin is low or into READY mode if the EN pin is high. In the SLEEP or READY state, the TDC1011 is able to receive SPI commands to set registers and configure the device for a measurement mode.

Device Function Description (continued)
NOTE

Although the SPI block is always active, it is not recommended to perform configuration changes while the device is active. Configuration changes should be performed while the device is in the SLEEP state or in the READY state.

If the EN pin is high and a trigger signal is received, the state machine will begin the execution of the configured measurement. The state machine will return to the SLEEP state after the measurement is completed.

The device can be forced to exit a measurement by applying a logic high on the RESET pin high or a logic low on the EN pin.

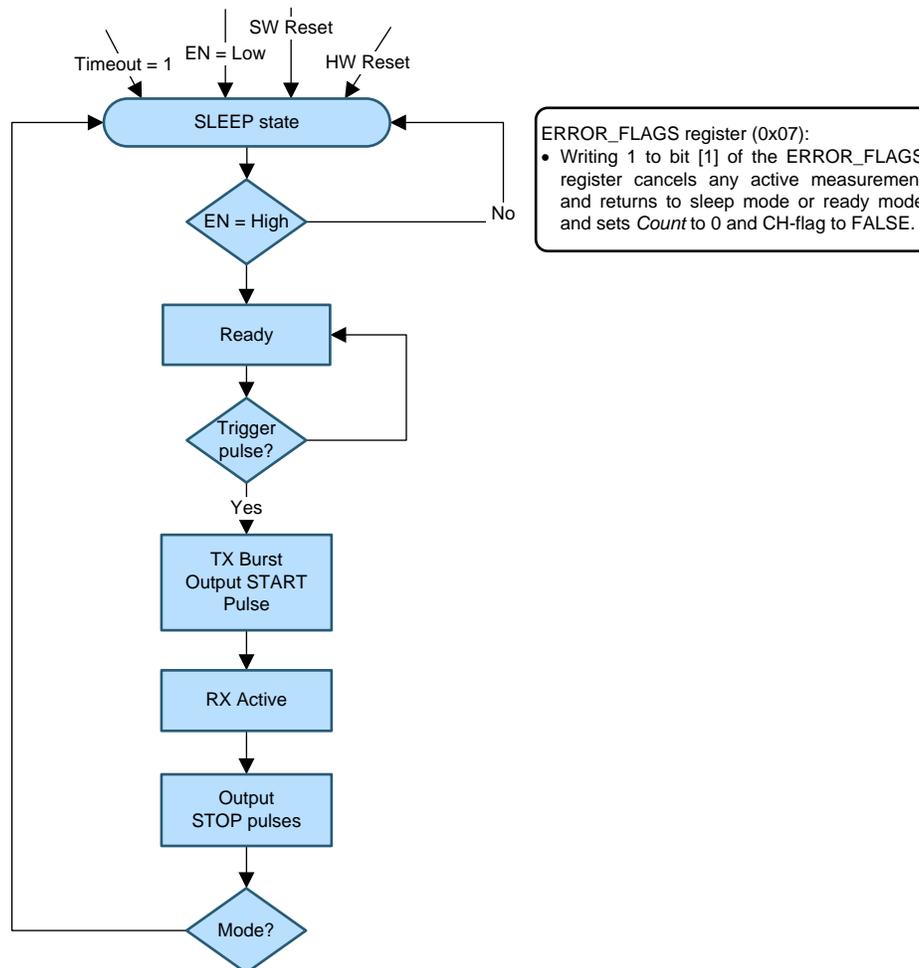


Figure 28. Simplified TDC1011 State Machine Diagram

Device Function Description (continued)

8.4.3 TRANSMIT Operation

8.4.3.1 Transmission Pulse Count

The number of TX pulses generated by the TDC1011 to drive an ultrasonic transducer is programmable using the `NUM_TX` field located in the `CONFIG_0` register.

8.4.3.2 TX 180° Pulse Shift

As shown in [Figure 29](#), the transmitter block can add a 180° shift at a position in the TX signal. The position of the pulse shift is set by the `TX_PH_SHIFT_POS` field in the `CONFIG_4` register and allows generating a specific signal pattern.

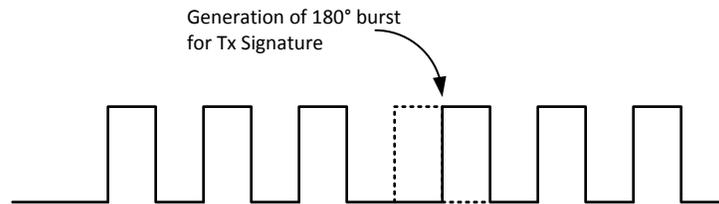


Figure 29. Transmitter Pulse Signature, 180° Burst

As shown in [Figure 30](#), enabling the TX 180° pulse shift has the effect of decreasing the number of transmitted pulses by 1.

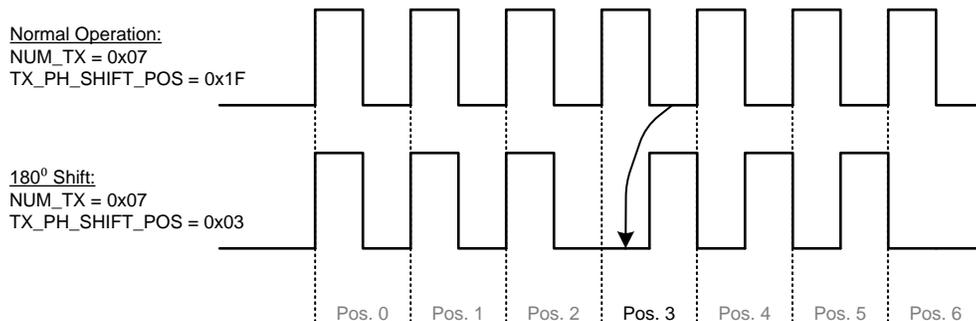


Figure 30. Transmitter Pulse Signature

In some cases, the 180° pulse shift may help improving the turn-off time of a transducer, and thus suppress the transmit ringing.

The 180° pulse shift is disabled by setting `TX_PH_SHIFT_POS` to position 31. Setting the 180° pulse shift to positions 0 or 1 is not recommended.

8.4.3.3 Transmitter Damping

The transmitter damping feature allows for improved control over the transducer signal generation. Damping extends the duration of the last TX pulse to help dissipate ringing and improve the transducer's turn-off time (see [Figure 31](#) and [Figure 32](#)). The accuracy of measurements can be improved by having a faster transducer turn-off time. Damping is controlled with the `DAMPING` bit in the `CONFIG_2` register.

Device Function Description (continued)

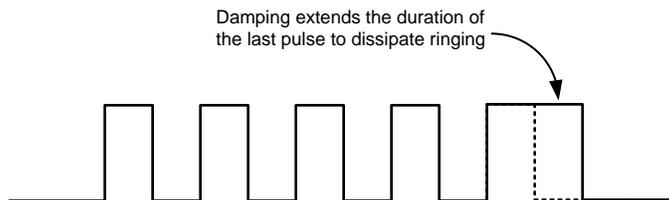


Figure 31. Transmitter Damping (5 Tx Pulses With a Damping Pulse)

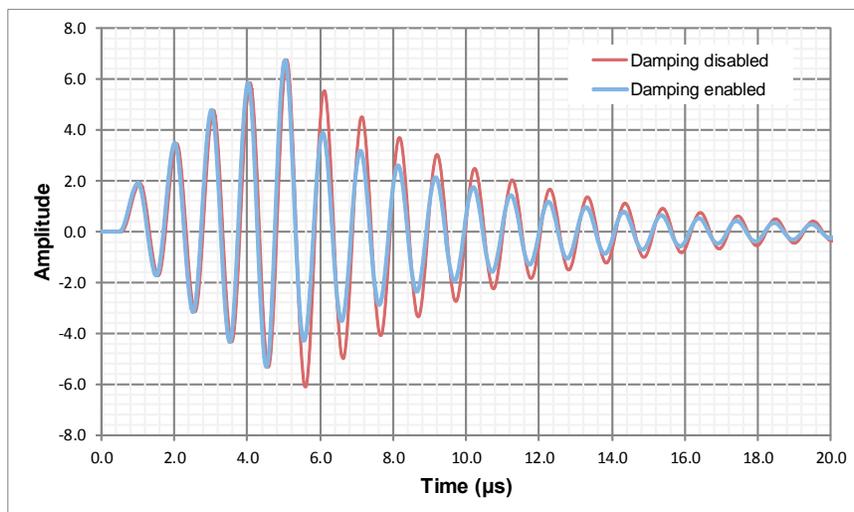


Figure 32. Transmitter Damped Echo

There are two invalid use combinations of the damping feature that may result in unexpected behavior. First, damping should not be combined with the 180° pulse shift described in the previous section. Second, damping should not be enabled if the number of TX pulses is set to 31.

8.4.4 RECEIVE Operation

8.4.4.1 Single Echo Receive Mode

Single Echo mode can be used for fluid identification measurements or level applications where transducer carrier frequency information is required. The device can be configured for Single Echo mode by setting the *RECEIVE_MODE* bit to 0 in the *CONFIG_4* register. In Single Echo mode, the device will generate STOP pulses for every zero-cross qualified by the threshold comparator, up to the number of expected STOP events configured in the *NUM_RX* field in the *CONFIG_1* register.

The threshold comparator qualifies the next zero-cross after an RX amplitude smaller than the programmed threshold voltage is detected. The zero-cross detector will provide output pulses corresponding to the rising edge of the received signal crossing the V_{COM} level, as shown in [Figure 33](#). The threshold voltage can be set in the *ECHO_QUAL_THDL* field in the *CONFIG_3* register.

Device Function Description (continued)

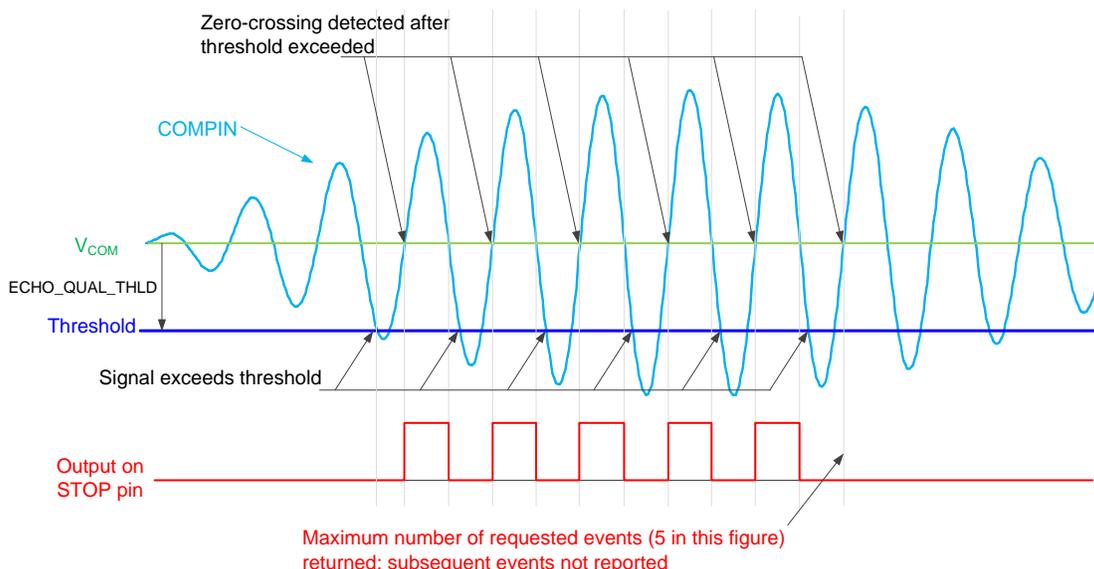


Figure 33. Single Echo Receive Mode (5 STOP Events)

If the number of expected pulses programmed in *NUM_RX* is not received or the time-of-flight operation times out, the TDC1011 will indicate an error condition in the *ERROR_FLAGS* register and will set the *ERRB* pin low.

8.4.4.2 Multiple Echo Receive Mode

The Multiple Echo mode is intended for use in level sensing applications and distance/displacement measurements in which multiple echoes (burst) are received. In this condition, each received echo group will be treated as a single pulse on the STOP pin. Up to 7 STOP pulses can be generated based on the value of the *NUM_RX* field in the *CONFIG_1* register. Multi echo mode can be enabled by setting the *RECEIVE_MODE* bit to 1 in the *CONFIG_4* register. A representation of multiple echo STOP pulse generation is shown in Figure 34.

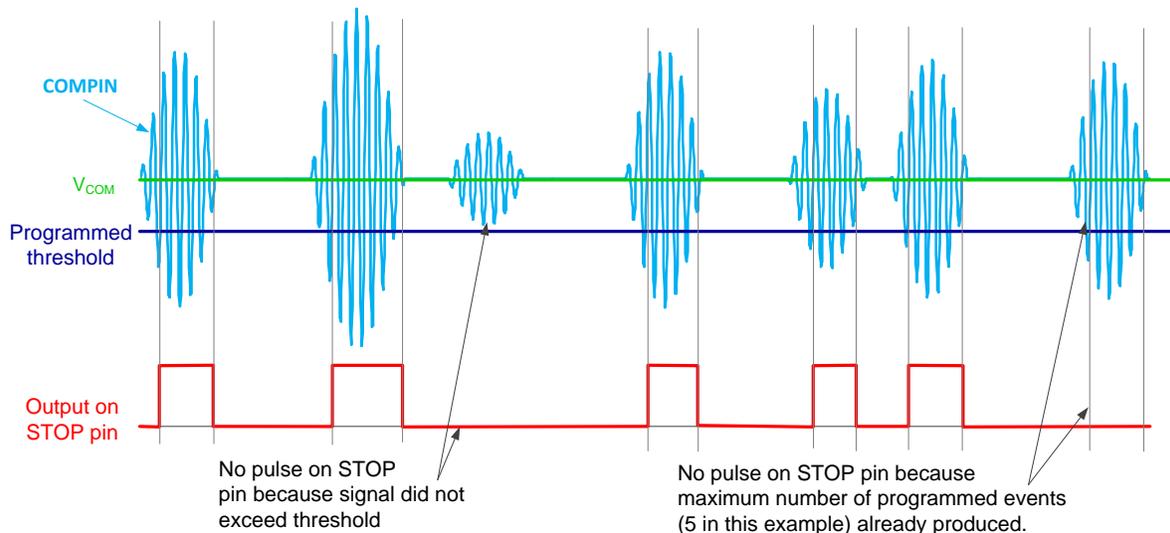


Figure 34. Multiple Echo Receive Mode (5 STOP Events)

Device Function Description (continued)

The rising edge of a STOP pulse is generated by a zero-crossing event. As in the Single Echo Receive Mode, the threshold comparator qualifies the next zero-cross after an RX amplitude smaller than the programmed threshold voltage is detected. The STOP pulse will extend until a zero-cross after the RX amplitude is no longer smaller than the threshold voltage (see Figure 35).

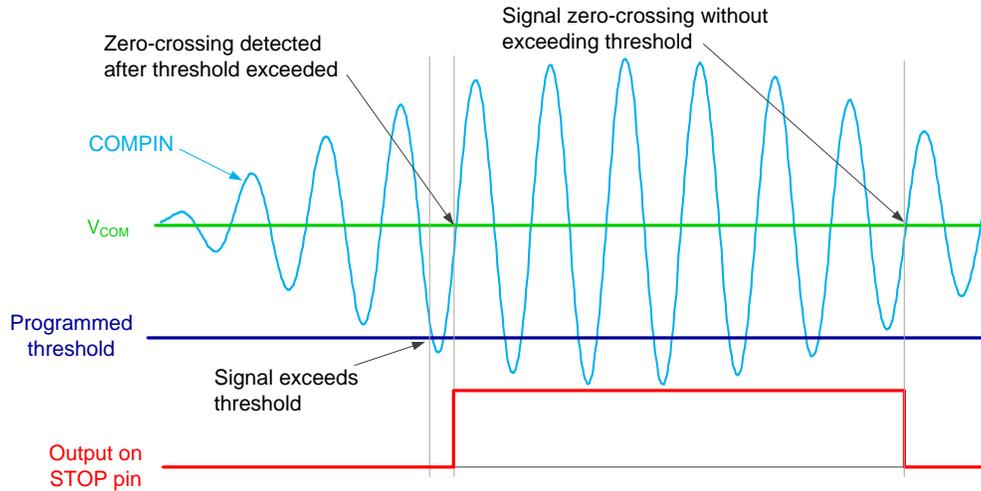


Figure 35. Multiple Echo Receive Mode (Zoom-in)

If the number of expected pulses programmed in *NUM_RX* is not received or the time-of-flight operation times out, the TDC1011 will indicate an error condition in the *ERROR_FLAGS* register and will set the ERRB pin low.

8.4.5 Timing

8.4.5.1 Timing Control and Frequency Scaling (CLKIN)

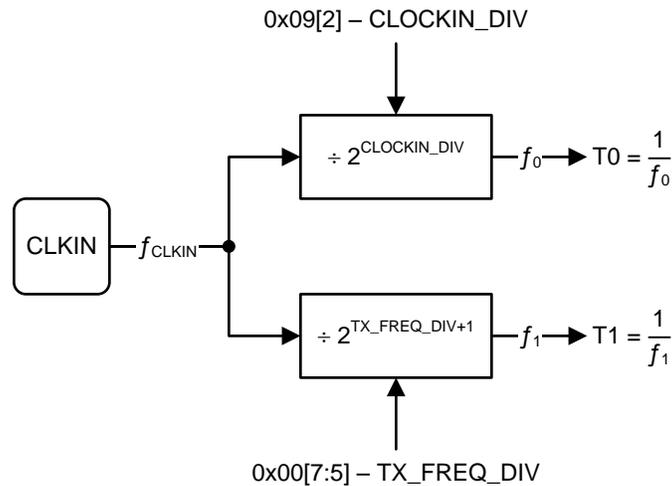


Figure 36. External Clock Division Tree

All transmit and receive function sequencing is synchronous to the external clock applied to the CLKIN pin. The external clock is divided to generate two internal clocks with corresponding time periods denoted as T0 and T1 in Figure 36. The division factor used to generate T0 is controlled with the *CLOCKIN_DIV* bit in the *CLOCK_RATE* register. The division factor used to generate T1 is controlled with the *TX_FREQ_DIV* field located in the *CONFIG_0* register.

The SPI block is synchronous with the clock applied to the SCLK pin, and it is independent of the clock applied to CLKIN. See the *Serial Peripheral Interface (SPI)* section for a complete description of the SPI block.

Device Function Description (continued)

8.4.5.2 TX/RX Measurement Sequencing and Timing

The TDC1011 automatically sequences the TX and RX functionality. After receiving a pulse edge on the TRIGGER pin, the TDC1011 resynchronizes to the CLKIN signal, and sends a TX burst.

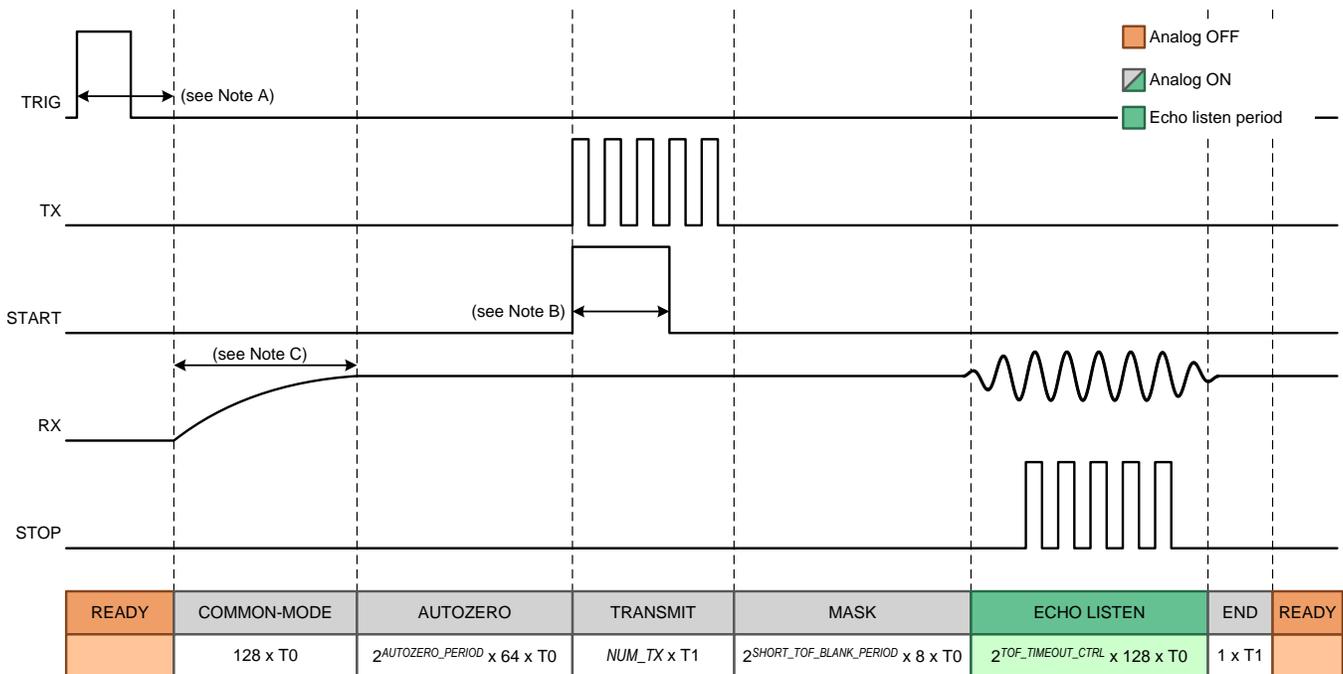
The trigger edge polarity is configured to rising edge by default, but it can be changed to falling edge by setting the *TRIG_EDGE_POLARITY* bit in the [CONFIG_4](#) register to 1.

After a device reset, the system must wait a determined time before sending the next trigger signal. The typical reset to trigger wait time is $3 \times T1 + 50$ ns.

8.4.6 Time-of-Flight (TOF) Control

The possible configurations of the TX/RX sequencing during a time-of-flight measurement can be divided into three cases: [Short TOF Measurement](#), [Standard TOF Measurement](#) and [Standard TOF Measurement with Power Blanking](#). Overall, the cases differ in the order of sequencing, power saving and echo listening windows. The behavior of each case is described in the sections to follow.

8.4.6.1 Short TOF Measurement



- A. Common-mode settling time.
- B. If $NUM_TX < 3$, the width of the START pulse is equal to $NUM_TX \times T1$. If $NUM_TX \geq 3$, the width of the START pulse is equal to $3 \times T1$.

Figure 37. Short TOF Measurement

In a short time of flight measurement, the RX path is activated before the TX burst, as shown in [Figure 37](#).

The short TOF is the default measurement sequence selected at power-on. The short TOF measurement is selected if the value of the *TIMING_REG[9:0]* field is less than 30, or if the *FORCE_SHORT_TOF* bit is set to 1. The *TIMING_REG[9:0]* is a 10-bit wide field, with its 2 most significant bits located in the [TOF_1](#) register, and the 8 least significant bits located in the [TOF_0](#) register. The *FORCE_SHORT_TOF* bit is located in the [TIMEOUT](#) register.

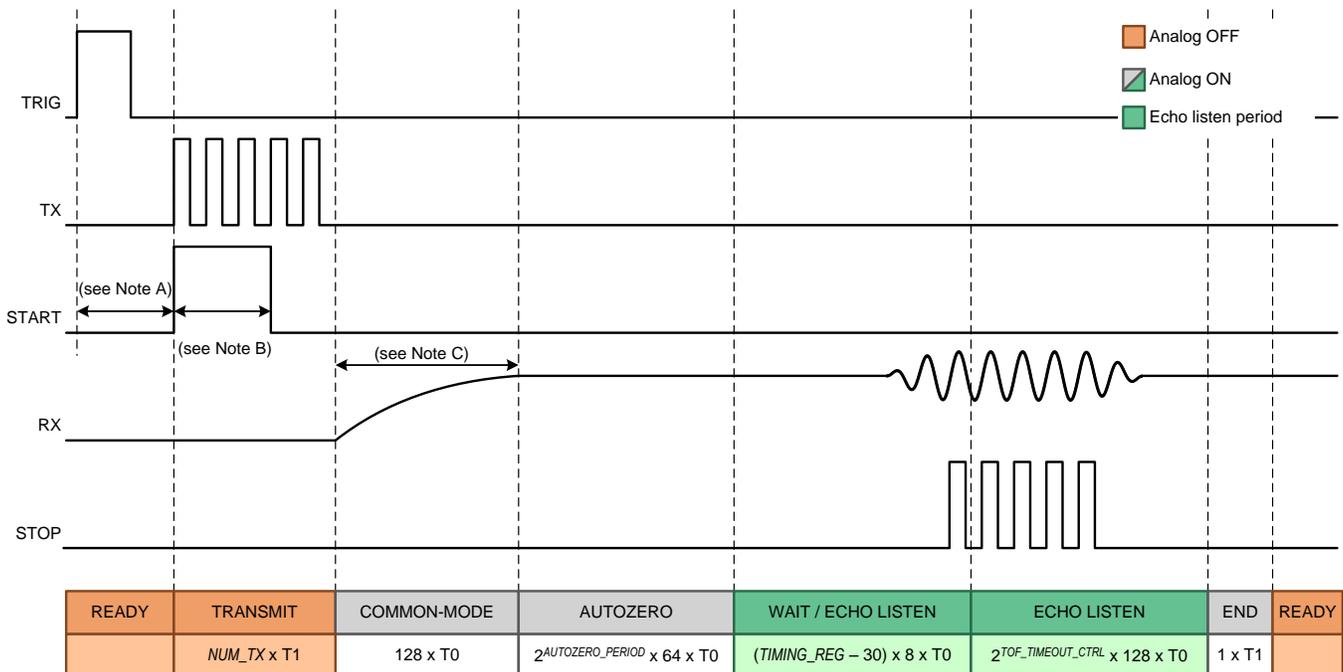
The comparator's input offset is stored in an internal capacitor during the auto-zero period. The length of the auto-zero period is controlled by the *AUTOZERO_PERIOD* field in the [CLOCK_RATE](#) register.

Device Function Description (continued)

The length of the window when the comparators are able to qualify and generate STOP pulses is configured by the `TOF_TIMEOUT_CTRL` field. A timeout will occur if the number of expected pulses is not received during the allocated time and an error condition is reported to the `ERROR_FLAGS` register and the ERRB pin. It is possible to disable the echo timeout (see [TOF Measurement Interval](#)). The `TOF_TIMEOUT_CTRL` field is located in the `TIMEOUT` register.

See the [Timing Control and Frequency Scaling \(CLKIN\)](#) section for the definition of the time periods T0 and T1.

8.4.6.2 Standard TOF Measurement



- Clock alignment.
- If $NUM_TX < 3$, the width of the START pulse is equal to $NUM_TX \times T1$. If $NUM_TX \geq 3$, the width of the START pulse is equal to $3 \times T1$.
- Common-mode settling time.

Figure 38. Standard TOF Measurement

In a standard time of flight measurement, the RX path is activated after the TX burst is completed, as shown in [Figure 38](#).

The standard TOF measurement sequence is enabled if the value of the `TIMING_REG` field is greater than or equal to 30, and only if the `FORCE_SHORT_TOF` bit is set to 0. The `TIMING_REG` is a 10-bit wide field, with its 2 most significant bits located in the `TOF_1` register, and the 8 least significant bits located in the `TOF_0` register. The `FORCE_SHORT_TOF` bit is located in the `TIMEOUT` register.

The comparator's input offset is stored in an internal capacitor during the auto-zero period. The length of the auto-zero period is controlled by the `AUTOZERO_PERIOD` field in the `CLOCK_RATE` register.

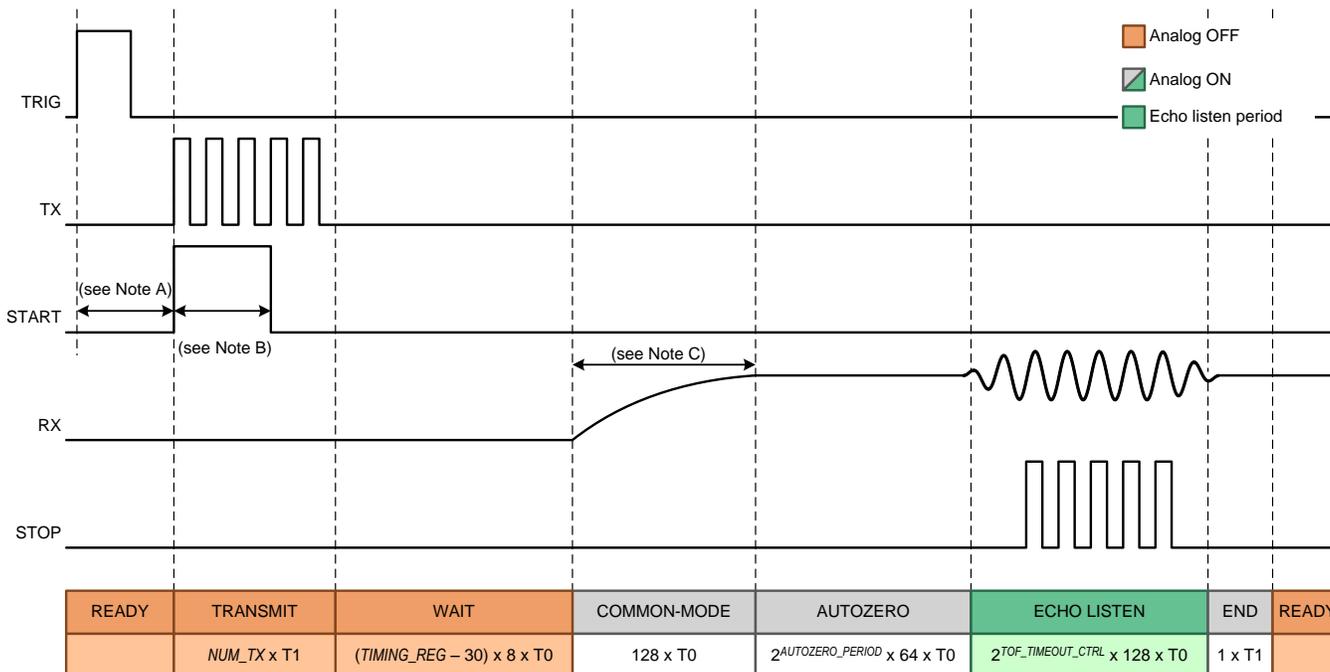
The length of the window when the comparators are able to qualify and generate STOP pulses is configured by a combination of the `TIMING_REG` field and the `TOF_TIMEOUT_CTRL` field. With the addition of the `TIMING_REG` in the calculation, the standard TOF measurement allows for a longer wait time and listening window. A timeout will occur if the number of expected pulses is not received during the allocated time and an error condition is reported to the `ERROR_FLAGS` register and the ERRB pin. It is possible to disable the echo timeout (see [TOF Measurement Interval](#)). The `TOF_TIMEOUT_CTRL` field is located in the `TIMEOUT` register.

Device Function Description (continued)

NOTE

If the *FORCE_SHORT_TOF* bit = 1, the measurement sequencing will behave as a **Short TOF Measurement**, thus overriding the setting of the *TIMING_REG* field.

8.4.6.3 Standard TOF Measurement with Power Blanking



- A. Clock alignment.
- B. If $NUM_TX < 3$, the width of the START pulse is equal to $NUM_TX \times T1$. If $NUM_TX \geq 3$, the width of the START pulse is equal to $3 \times T1$.
- C. Common-mode settling time.

Figure 39. Standard TOF Measurement with Blanking Enabled

The power blanking sequence is a variation to the standard TOF measurement sequence, and can be enabled by setting the *BLANKING* bit to 1. In addition, all other conditions described in the *Standard TOF Measurement* should be met. The *BLANKING* bit can be found in the *CONFIG_3* register.

Power blanking allows the device to remain in a low-power state while the TX signals propagate to the RX transducer in situations when the expected time-of-flight is long. Power blanking uses the *TIMING_REG* to control a wait time between the transmit sequence and the receive sequence, during which, the complete RX chain is disabled, as shown in *Figure 39*. The *TIMING_REG* is a 10-bit wide field, with its 2 most significant bits located in the *TOF_1* register, and the 7 least significant bits located in the *TOF_0* register.

8.4.6.4 Common-mode Reference Settling Time

The duration of the common-mode settling *time* is defined by the VCOM capacitor. With a 10-nF VCOM capacitor, the common-mode reference requires 16 μ s to settle. On the other hand, the duration of the common-mode settling *window* is defined as $128 \times T0$, where the time unit $T0$ is determined by the external clock frequency and the value of the *CLOCKIN_DIV* bit, as explained in the *Timing Control and Frequency Scaling (CLKIN)* section.

A frequency of 8 MHz will result in a settling *window* of $128 \times 1 / 8$ MHz, which equals to 16 μ s. Increasing the value of the VCOM capacitor will increase the common-mode settling *time*, but for the same 8-MHz frequency, the duration of the common-mode settling *window* will remain at 16 μ s. In such situation, the common-mode reference will take multiple TOF cycles to reach its final value when starting from zero initial conditions.

Device Function Description (continued)

8.4.6.5 TOF Measurement Interval

The comparators in the TDC1011's RX path can qualify and generate STOP pulses from a received echo within an interval set by the *TOF_TIMEOUT_CTRL* field in the [TIMEOUT](#) register. The listening interval can be extended in the standard TOF measurement (without blanking) by a period controlled with the *TIMING_REG* field (see [Standard TOF Measurement](#)).

If the number of STOP events programmed in the *NUM_RX* field is not received within the listening interval, a timeout event will occur and the device will return to the READY state. In addition, an error will be reported to the [ERROR_FLAGS](#) register and the ERRB pin will be driven low.

The echo timeout can be disabled by setting the *ECHO_TIMEOUT* bit to 1 in the [TIMEOUT](#) register. If the echo timeout is disabled, the device will not exit from the receive state until the expected number of STOP events set in *NUM_RX* occur. If the number of events does not occur, the device can be forced out of the receive state by writing a value of 0x03 to the [ERROR_FLAGS](#) register, or by de-asserting the EN pin, or asserting the RESET pin.

NOTE

Writing a logic 1 to bit [1] of the [ERROR_FLAGS](#) register clears the state machine. Writing a logic 1 to bit[0] clears the error flags.

NOTE

It is not recommended to hold the RX in an active state for intervals longer than 100ms, as the comparator auto-zero may no longer be accurate.

8.4.7 Error Reporting

The TDC1011 will report an error when the receive signals do not match the expected configuration. The ERRB pin will go low to indicate the presence of an error condition. Reading the [ERROR_FLAGS](#) register provides information about the condition(s) that caused the error.

The *ERR_SIG_WEAK* bit indicates that the number of received and qualified zero-crossings was less than the expected number set in the *NUM_RX* register field and a timeout occurred. This error is cleared when bit [0] is written to 1.

The *ERR_NO_SIG* bit indicates that no signals were received and a timeout occurred. Writing a 1 to this bit resets the state machine, halts active measurements and returns the device to SLEEP or READY mode. This error is cleared when bit [0] is written to 1.

The *ERR_SIG_HIGH* bit indicates that the received echo amplitude exceeds the largest echo qualification threshold at the input of the comparators. The *ERR_SIG_HIGH* error is only reported when the *ECHO_QUAL_THDL* register field is set to 7h. Writing a 1 to this bit will reset all the error flags and reset the ERRB pin to high.

NOTE

It is recommended to reset the state machine when the error flags are cleared. This can be done simultaneously by writing a value of 0x03 to the [ERROR_FLAGS](#) register.

8.5 Programming

8.5.1 Serial Peripheral Interface (SPI)

The serial interface consists of serial data input (SDI), serial data output (SDO), serial interface clock (SCLK) and chip select bar (CSB). The serial interface is used to configure the TDC1011 parameters available in various configuration registers. All the registers are organized into individually addressable byte-long registers with a unique address.

Programming (continued)

The communication on the SPI bus normally supports write and read transactions. A write transaction consists of a single write command byte, followed by single data byte. A read transaction consists of a single read command byte followed by 8 SCLK cycles. The write and read command bytes consist of 1 reserved bit, a 1-bit instruction, and a 6-bit register address. Figure 40 shows the SPI protocol for a transaction involving one byte of data (read or write).

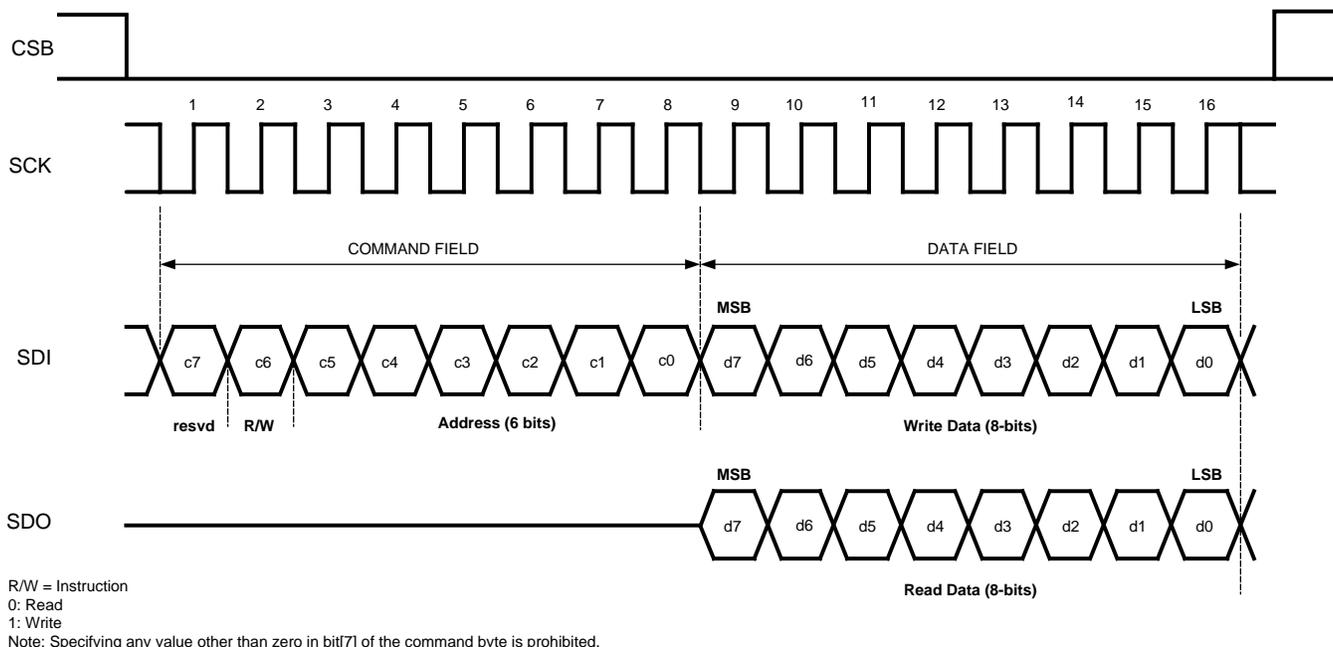


Figure 40. SPI Protocol

8.5.1.1 Chip Select Bar (CSB)

CSB is an active-low signal and needs to be low throughout a transaction. That is, CSB should not pulse between the command byte and the data byte of a single transaction.

De-asserting CSB always terminates an ongoing transaction, even if it is not yet complete. Re-asserting CSB will always bring the device into a state ready for the next transaction, regardless of the termination status of a previous transaction.

8.5.1.2 Serial Clock (SCLK)

SCLK can idle high or low. It is recommended to keep SCLK as clean as possible to prevent glitches from corrupting the SPI frame.

8.5.1.3 Serial Data Input (SDI)

SDI is driven by the SPI master by sending the command and the data byte to configure the AFE.

8.5.1.4 Serial Data Output (SDO)

SDO is driven by the AFE when the SPI master initiates a read transaction.

8.6 Register Maps

NOTE

- Reserved bits must be written to 0 unless otherwise indicated.
- Read-back value of reserved bits and registers is unspecified and should be discarded.
- Recommended values must be programmed and forbidden values must not be programmed where they are indicated to avoid unexpected results.

8.6.1 TDC1011 Registers

Table 3 list the memory-mapped registers for the TDC1011. All register addresses not listed in Table 3 should be considered as reserved locations and the register contents should not be modified.

Table 3. TDC1011 REGISTERS

Address (Hex)	Acronym	Register Name	Reset Value	Section
0h	CONFIG_0	Config-0	45h	See here
1h	CONFIG_1	Config-1	40h	See here
2h	CONFIG_2	Config-2	0h	See here
3h	CONFIG_3	Config-3	3h	See here
4h	CONFIG_4	Config-4	1Fh	See here
5h	TOF_1	TOF-1	0h	See here
6h	TOF_0	TOF-0	0h	See here
7h	ERROR_FLAGS	Error Flags	0h	See here
8h	TIMEOUT	Timeout	19h	See here
9h	CLOCK_RATE	Clock Rate	0h	See here

8.6.1.1 CONFIG_0 Register (address = 0h) [reset = 45h] (map)

Figure 41. CONFIG_0 Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
TX_FREQ_DIV				NUM_TX			
R/W-2h				R/W-5h			

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 4. CONFIG_0 Register Field Descriptions

Bit	Field	Type	Reset	Description
[7:5]	TX_FREQ_DIV ⁽¹⁾	R/W	2h	Frequency divider for TX clock and T1 0h: Divide by 2 1h: Divide by 4 2h: Divide by 8 (default) 3h: Divide by 16 4h: Divide by 32 5h: Divide by 64 6h: Divide by 128 7h: Divide by 256
[4:0]	NUM_TX	R/W	5h	Number of TX pulses in a burst, ranging from 0 to 31. 5h: 5 pulses (default)

(1) See [Timing Control and Frequency Scaling \(CLKIN\)](#) for the definition of the time period T1.

8.6.1.2 CONFIG_1 Register (address = 1h) [reset = 40h] (map)
Figure 42. CONFIG_1 Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
RESERVED		RESERVED			NUM_RX		
R/W-1h		R/W-0h			R/W-0h		

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 5. CONFIG_1 Register Field Descriptions

Bit	Field	Type	Reset	Description
[7:6]	RESERVED	R/W	1h	1h: Reserved (default)
[5:3]	RESERVED	R/W	0h	Must always be written 0h (default)
[2:0]	NUM_RX	R/W	0h	Number of expected receive events 0h: Do not count events (32 STOP pulses output) (default) 1h: 1 event (1 STOP pulse output) 2h: 2 events (2 STOP pulses output) 3h: 3 events (3 STOP pulses output) 4h: 4 events (4 STOP pulses output) 5h: 5 events (5 STOP pulses output) 6h: 6 events (6 STOP pulses output) 7h: 7 events (7 STOP pulses output)

8.6.1.3 CONFIG_2 Register (address = 2h) [reset = 0h] (map)
Figure 43. CONFIG_2 Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
VCOM_SEL	MEAS_MODE	DAMPING	RESERVED				
R/W-0h	R/W-0h	R/W-0h	R/W-0h				

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 6. CONFIG_2 Register Field Descriptions

Bit	Field	Type	Reset	Description
[7]	VCOM_SEL	R/W	0h	Common-mode voltage reference control 0h: Internal (default) 1h: External
[6]	MEAS_MODE	R/W	0h	AFE measurement type 0h: Time-of-flight measurement (default) 1h: Temperature measurement
[5]	DAMPING	R/W	0h	TX burst damping 0h: Disable damping (default) 1h: Enable damping
[4:0]	RESERVED	R/W	0h	Must always be written 0h (default)

8.6.1.4 CONFIG_3 Register (address 3h) [reset = 3h] (map)
Figure 44. CONFIG_3 Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
RESERVED	TEMP_MODE	TEMP_RTD_SEL	TEMP_CLK_DIV	BLANKING	ECHO_QUAL_THLD		
R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-3h		

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 7. CONFIG_3 Register Field Descriptions

Bit	Field	Type	Reset	Description
[7]	RESERVED	R/W	0h	0h: Reserved (default)
[6]	TEMP_MODE	R/W	0h	Temperature measurement channels 0h: Measure REF, RTD1 and RTD2 (default) 1h: Measure REF and RTD1
[5]	TEMP_RTD_SEL	R/W	0h	RTD type 0h: PT1000 (default) 1h: PT500
[4]	TEMP_CLK_DIV	R/W	0h	Clock divider for temperature mode 0h: Divide by 8 (default) 1h: Use TX_FREQ_DIV
[3]	BLANKING	R/W	0h	Power blanking in standard TOF measurements. The blanking length is controlled with the TIMING_REG field (see Standard TOF Measurement with Power Blanking). 0h: Disable power blanking (default) 1h: Enable power blanking
[2:0]	ECHO_QUAL_THLD	R/W	3h	Echo qualification DAC threshold level with respect to V_{COM} 0h: -35 mV 1h: -50 mV 2h: -75 mV 3h: -125 mV (default) 4h: -220 mV 5h: -410 mV 6h: -775 mV 7h: -1500 mV

8.6.1.5 CONFIG_4 Register (address = 4h) [reset = 1Fh] (map)
Figure 45. CONFIG_4 Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
RESERVED	RECEIVE_MODE	TRIG_EDGE_POLARITY	TX_PH_SHIFT_POS				
R/W-0h	R/W-0h	R/W-0h	R/W-1Fh				

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 8. CONFIG_4 Register Field Descriptions

Bit	Field	Type	Reset	Description
[7]	RESERVED	R/W	0h	0h: Reserved (default)
[6]	RECEIVE_MODE	R/W	0h	Receive echo mode 0h: Single echo (default) 1h: Multi echo
[5]	TRIG_EDGE_POLARITY	R/W	0h	Trigger edge polarity 0h: Rising edge (default) 1h: Falling edge
[4:0]	TX_PH_SHIFT_POS	R/W	1Fh	TX 180° pulse shift position, ranging from 0 to 31. 1Fh: Position 31 (default) It is not recommended to set TX_PH_SHIFT_POS to 0 or 1.

8.6.1.6 TOF_1 Register (address = 5h) [reset = 0h] (map)
Figure 46. TOF_1 Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
PGA_GAIN		PGA_CTRL		LNA_CTRL	LNA_FB	TIMING_REG[9:8]	
R/W-0h		R/W-0h		R/W-0h	R/W-0h	R/W-0h	

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 9. TOF_1 Register Field Descriptions

Bit	Field	Type	Reset	Description
[7:5]	PGA_GAIN	R/W	0h	PGA gain 0h: 0 dB (default) 1h: 3 dB 2h: 6 dB 3h: 9 dB 4h: 12 dB 5h: 15 dB 6h: 18 dB 7h: 21 dB
[4]	PGA_CTRL	R/W	0h	PGA control 0h: Active (default) 1h: Bypassed and powered off
[3]	LNA_CTRL	R/W	0h	LNA control 0h: Active (default) 1h: Bypassed and powered off
[2]	LNA_FB	R/W	0h	LNA feedback mode 0h: Capacitive feedback (default) 1h: Resistive feedback
[1:0]	TIMING_REG[9:8]	R/W	0h	TIMING_REG field's 2 most-significant bits (see Standard TOF Measurement and Standard TOF Measurement with Power Blanking) 0h: 0 (default)

8.6.1.7 TOF_0 Register (address = 6h) [reset = 0h] (map)
Figure 47. TOF_0 Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
TIMING_REG[7:0]							
R/W-0h							

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 10. TOF_0 Register Field Descriptions

Bit	Field	Type	Reset	Description
[7:0]	TIMING_REG[7:0]	R/W	0h	TIMING_REG field's 8 least-significant bits (see Standard TOF Measurement and Standard TOF Measurement with Power Blanking) 0h: 0 (default)

8.6.1.8 ERROR_FLAGS Register (address = 7h) [reset = 0h] (map)
Figure 48. ERROR_FLAGS Register

7 (MSB)	6	5	4	3	2	1	0 (LSB)
RESERVED					ERR_SIG_WEAK	ERR_NO_SIG	ERR_SIG_HIGH
R-0h					R-0h	R/W1C-0	R/W1C-0

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 11. ERROR_FLAGS Register Field Descriptions⁽¹⁾⁽²⁾

Bit	Field	Type	Reset	Description
[7:3]	RESERVED	R	0h	0h: Reserved (default)
[2]	ERR_SIG_WEAK	R	0h	1h: The number of received and qualified zero-crossings was less than the expected number set in NUM_RX field and a timeout occurred.
[1]	ERR_NO_SIG	R/W1C	0h	1h: No signals were received and timeout occurred. Writing a 1 to this field resets the state machine, halts active measurements and returns the device to the SLEEP or READY mode.
[0]	ERR_SIG_HIGH	R/W1C	0h	1h: The received echo amplitude exceeds the largest echo qualification threshold at the input of the comparators. The error is only reported when ECHO_QUAL_THLD = 0x07. Writing a 1 to this field will reset all the error flags and reset the ERRB pin to high.

(1) It is recommended to read the error status register or the ERRB pin before initiating a new measurement.

(2) All error flags should be cleared before initiating a new measurement.

8.6.1.9 TIMEOUT Register (address = 8h) [reset = 19h] (map)
Figure 49. TIMEOUT Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
RESERVED	FORCE_SHORT_TOF	SHORT_TOF_BLANK_PERIOD			ECHO_TIMEOUT	TOF_TIMEOUT_CTRL	
R/W-0h	R/W-0h	R/W-3h			R/W-0h	R/W-1h	

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 12. TIMEOUT Register Field Descriptions

Bit	Field	Type	Reset	Description
[7]	RESERVED	R/W	0h	0h: Reserved (default)
[6]	FORCE_SHORT_TOF	R/W	0h	Short time-of-flight control 0h: Disabled (default) 1h: Force a short time-of-flight measurement
[5:3]	SHORT_TOF_BLANK_PERIOD ⁽¹⁾	R/W	3h	Short time-of-flight blanking period (see Short TOF Measurement) 0h: 8 × T ₀ 1h: 16 × T ₀ 2h: 32 × T ₀ 3h: 64 × T ₀ (default) 4h: 128 × T ₀ 5h: 256 × T ₀ 6h: 512 × T ₀ 7h: 1024 × T ₀

 (1) See [Timing Control and Frequency Scaling \(CLKIN\)](#) for the definition of the time period T₀.

Table 12. TIMEOUT Register Field Descriptions (continued)

Bit	Field	Type	Reset	Description
[2]	ECHO_TIMEOUT	R/W	0h	Echo receive timeout control (see TOF Measurement Interval) 0h: Enable echo timeout (default) 1h: Disable timeout
[1:0]	TOF_TIMEOUT_CTRL ⁽¹⁾	R/W	1h	Echo listening window timeout (see TOF Measurement Interval) 0h: 128 × T0 1h: 256 × T0 (default) 2h: 512 × T0 3h: 1024 × T0

8.6.1.10 CLOCK_RATE Register (address = 9h) [reset = 0h] (map)
Figure 50. CLOCK_RATE Register

(MSB) 7	6	5	4	3	2	1	0 (LSB)
RESERVED					CLOCKIN_DIV	AUTOZERO_PERIOD	
R/W-0h					R/W-0h	R/W-0h	

LEGEND: R/W = Read or write; R = Read only; R/W1C = Read or write 1 to clear

Table 13. CLOCK_RATE Register Field Descriptions⁽¹⁾

Bit	Field	Type	Reset	Description
[7:3]	RESERVED	R/W	0h	0h: Reserved (default)
[2]	CLOCKIN_DIV ⁽¹⁾	R/W	0h	CLKIN divider to generate T0 0h: Divide by 1 (default) 1h: Divide by 2
[1:0]	AUTOZERO_PERIOD ⁽¹⁾	R/W	0h	Receiver auto-zero period 0h: 64 × T0 (default) 1h: 128 × T0 2h: 256 × T0 3h: 512 × T0

(1) See [Timing Control and Frequency Scaling \(CLKIN\)](#) for the definition of the time period T0.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TDC1011 is an analog front-end for ultrasonic sensing applications. The device is typically used for the driving and sensing of ultrasonic transducers to perform accurate time-of-flight measurements. Ultrasonic time-of-flight sensing allows for fluid level, fluid identification or concentration measurements.

9.2 Typical Applications

9.2.1 Level and Fluid Identification Measurements

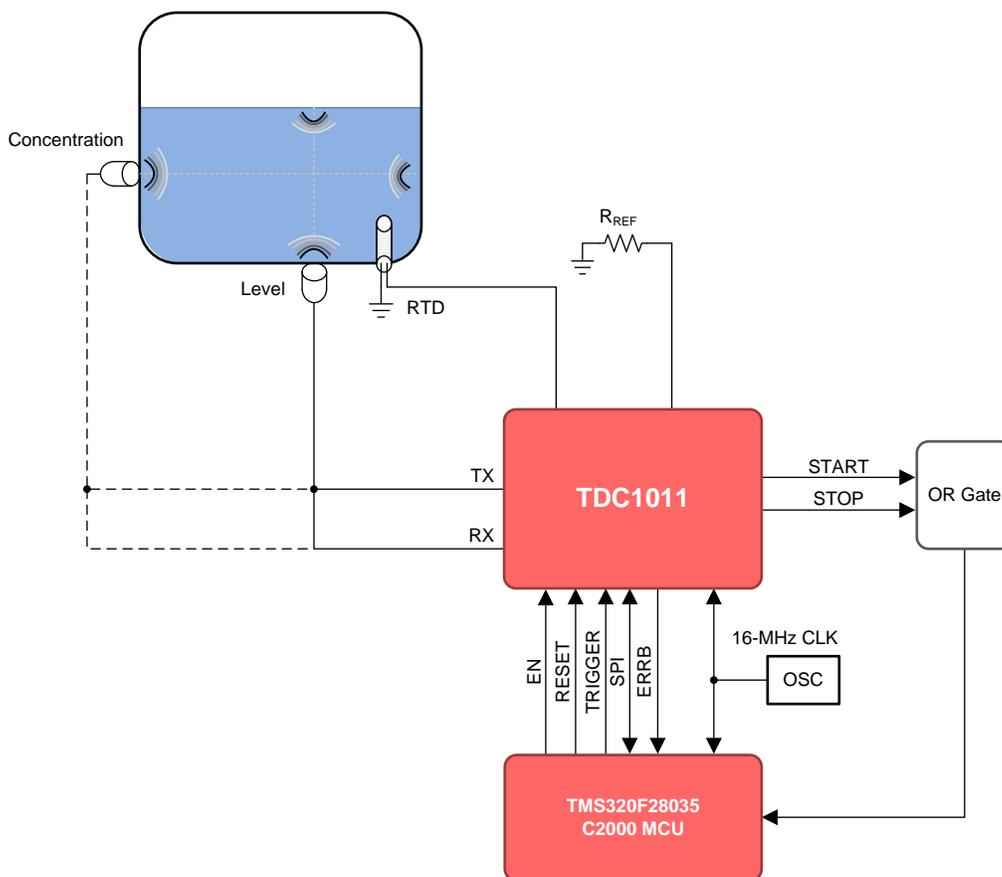


Figure 51. Level or Concentration Measurement Application Diagram

Typical Applications (continued)

9.2.1.1 Design Requirements

Table 14. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Fluid Level	
Range	2 – 10 cm
Fluid Identification	
Accuracy	0.5% concentration variation
Distance	5.08 cm

9.2.1.2 Detailed Design Procedure

9.2.1.2.1 Level Measurements

For level sensing applications, the total time-of-flight (TOF) of the sound wave in the fluid is measured. The pulses transmitted by a bottom mounted transducer travel through the fluid, to the surface of the fluid. The discontinuity between the fluid and air generates a reflected wave which returns back to the bottom mounted transducer.

At the beginning of a measurement cycle, the transducer is connected to a transmit channel of the AFE, and the transmit burst excites the transducer to generate an ultrasound wave. Synchronous to the TX burst, a START pulse is generated by the TDC1011 to indicate the start of a measurement. After the transmission is completed, and depending on the device configuration, the transducer is connected to a receive channel of the AFE.

When a valid echo is received, the TDC1011 generates a STOP pulse. Generation of multiple STOP pulses is possible through register configuration of the device. The START and STOP signal times are compared to determine the TOF.

The level of the fluid can be determined using the following equation:

$$d = \frac{TOF \times c}{2}$$

where

- d is the fluid level in meters (m)
 - TOF is the time-of-flight in seconds (s)
 - c is the speed of sound in the fluid in meters per second (m/s)
- (6)

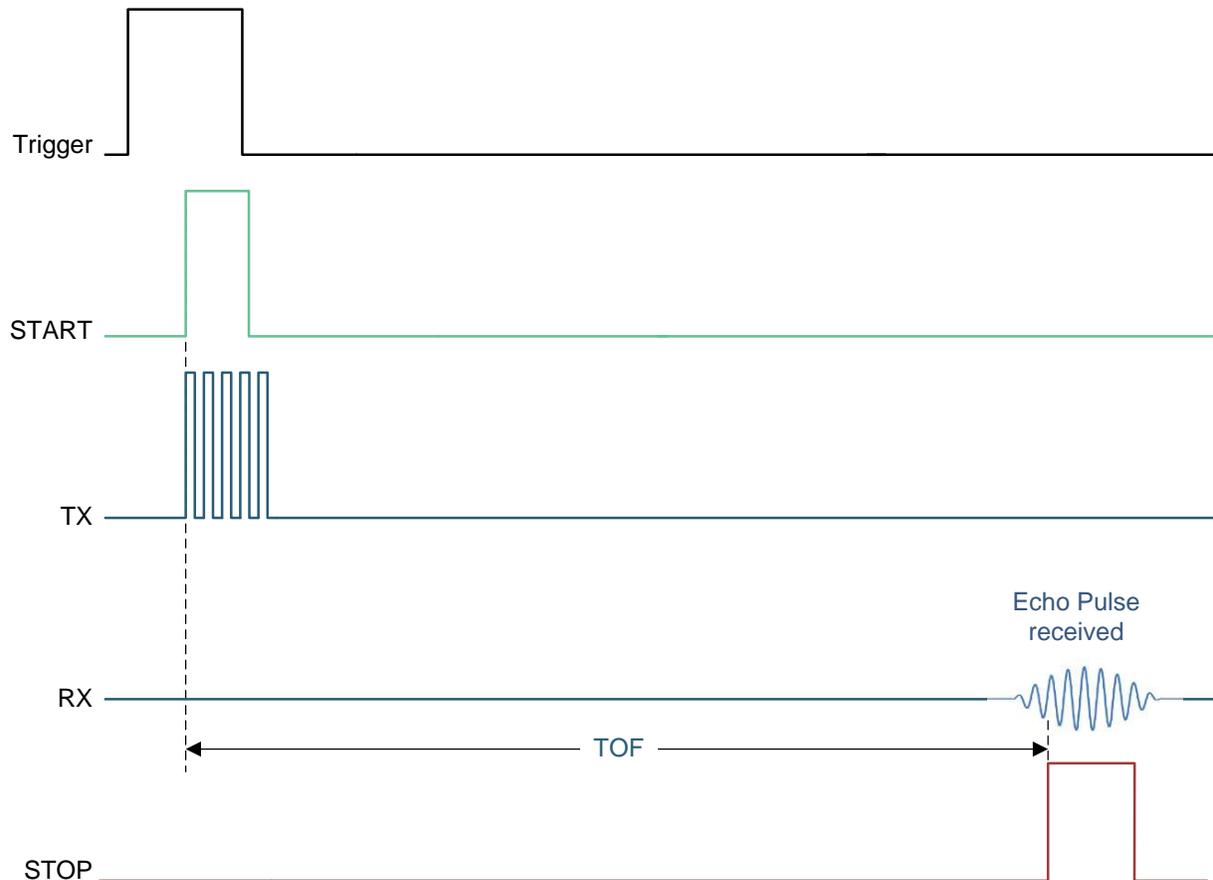


Figure 52. Relation Between Transmit and Receive Pulses in Level Measurements

Level measurements have 2 main criteria: resolution and range (maximum height). Resolution accuracies of 1-2 mm are achievable but are impractical due to any environmental disturbances, such as tank vibrations, creating millimeter level surface waves. Ranges of up to 1 m are measurable utilizing VDD level excitation pulses, but surface disturbances and signal loss over longer distances make the reliable echo reception an issue. Greater level measurement reception can be achieved by mechanical means (level guide tube) and/or electronic means (level shifting the TX pulses to greater voltages; see [TIDA-00322](#)).

9.2.1.2.2 Fluid Identification

The TDC1011 can be used to measure the time-of-flight for a known distance to calculate the speed of sound (c_{medium}) in the fluid. This application utilizes the same circuitry as the level example but a transducer in a side mounted configuration transmitting across the container or to a target at a known distance from the transducer.

The temperature can also be measured to compensate for the temperature variation of sound. With the known distance, TOF and temperature, the speed of sound in the fluid can be determined and the identity of the medium verified.

After measuring the time-of-flight for the fixed distance, the speed of sound can be calculated as follows:

$$c_{\text{medium}} = \frac{2 \times d}{TOF}$$

where

- c_{medium} is the speed of sound in the fluid in meters per second (m/s)
- d is the level in meters (m)
- TOF is the time of flight in seconds (s)

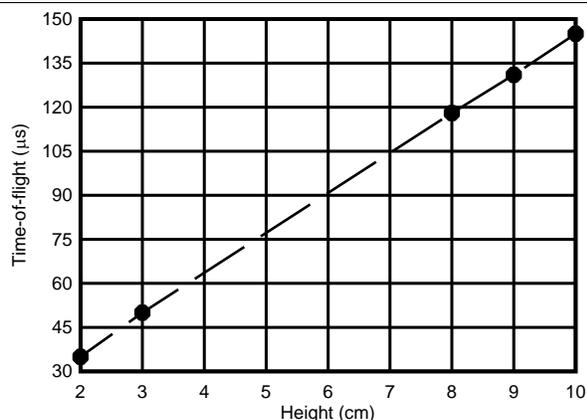
(7)

The measurement process is identical to the level example above. The speed of sound can be used to uniquely identify a variety of fluids. In this example, the concentration of diesel exhaust fluid (DEF) is measured with a desired accuracy resolution of 0.5% of concentration variation. For most fluids, the speed of sound varies over temperature, so every application will be different. In this example, all samples were all at ambient temperature of 23°C.

9.2.1.3 Application Curves

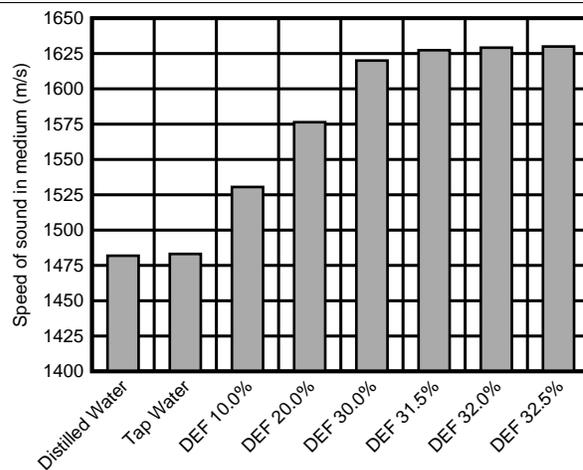
The data used in the following level and fluid identification graphs was collected using an ultrasonic test cell. The test cell is an acrylic plastic container with width of 2.54 cm and ultrasonic transducers attached to the outside using cyanoacrylate glue. The transducers in this experiment were STEMiNC 1MHz piezo electric ceramic discs (SMD10T2R111). Equivalent transducers with the following characteristics could be used:

- Piezo material: SM111
- Dimensions: 10mm diameter x 2mm thickness
- Resonant frequency: 1050 kHz (thickness mode)



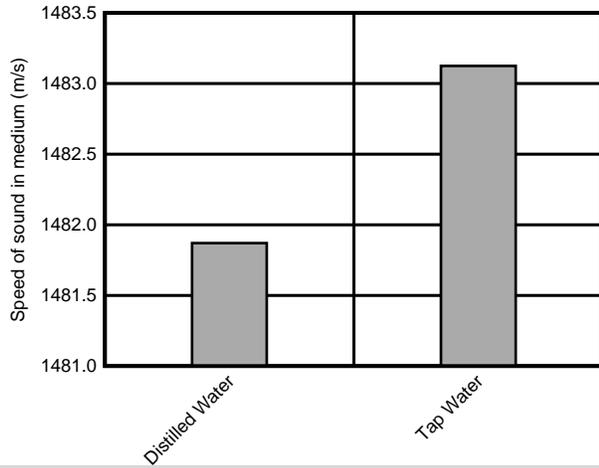
Fluid Height in Tank	Time-of-Flight (µs)
Full (10 cm)	145
Full – 1 (9 cm)	131
Full – 2 (8 cm)	118
3 cm	50
2 cm	35

Figure 53. Time-of-Flight for Fluid Height in Tank



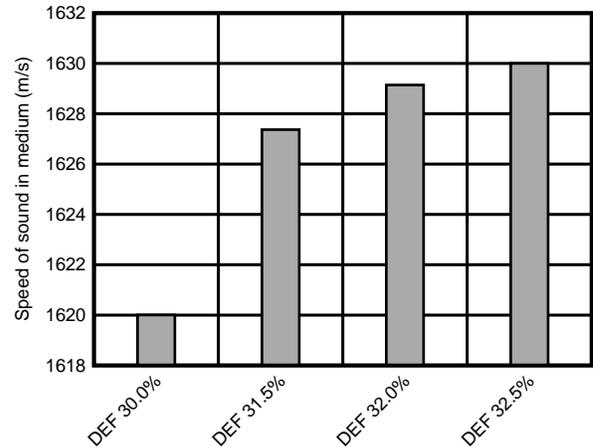
Fluid	Speed of sound (m/s)
Distilled water	1481.87
Tap water	1483.13
DEF 10.0%	1530.49
DEF 20.0%	1576.42
DEF 30.0%	1620.00
DEF 31.5%	1627.37
DEF 32.0%	1629.15
DEF 32.5%	1630.00

Figure 54. Speed of Sound for Various Fluids and Diesel Exhaust Fluid (DEF) Concentration



Fluid	Speed of sound (m/s)
Distilled water	1481.87
Tap water	1483.13

Figure 55. Speed of Sound in Distilled Water and Tap Water



Fluid	Speed of sound (m/s)
DEF 30.0%	1620.00
DEF 31.5%	1627.37
DEF 32.0%	1629.15
DEF 32.5%	1630.00

Figure 56. Speed of Sound of Various Diesel Exhaust Fluid (DEF) Concentrations

10 Power Supply Recommendations

The analog circuitry of the TDC1011 is designed to operate from an input voltage supply range between 2.7V and 5.5V. It is recommended to place a 100nF ceramic bypass capacitor to ground as close as possible to the VDD pins. In addition, an electrolytic or tantalum capacitor with value greater than 1 μ F is recommended. The bulk capacitor does not need to be in close vicinity with the TDC1011 and could be close to the voltage source terminals or at the output of the voltage regulators powering the TDC1011.

The IO circuitry of the TDC1011 is designed to operate from an input voltage supply range between 1.8V and 5.5V. The IO voltage supply (V_{IO}) can be lower than the analog voltage supply (V_{DD}), but it should not exceed it. It is also recommended to place a 100nF ceramic bypass capacitor to ground as close as possible to the VIO pin. If a separate source or regulator is used for VIO, an additional electrolytic or tantalum capacitor with value greater than 1 μ F is recommended.

In some cases an additional 10 μ F bypass capacitor may further reduce the supply noise.

11 Layout

11.1 Layout Guidelines

- In a 4-layer board design, the recommended layer stack order from top to bottom is: signal, ground, power and signal.
- Bypass capacitors should be placed in close proximity to the VDD and VIO pins.
- The length of the START and STOP traces from the DUT to the stopwatch/MCU should be matched to prevent uneven signal delays. Also, avoid unnecessary via-holes on these traces and keep the routing as short/direct as possible to minimize parasitic capacitance on the PCB.
- Match the length (or resistance) of the traces leading to the RTD sensors. PCB series resistance will be added in series to the RTD sensors.
- Route the SPI signal traces close together. Place a series resistor at the source of SDO (close to the DUT) and series resistors at the sources of SDI, SCLK and CSB (close to the master MCU).

11.2 Layout Example

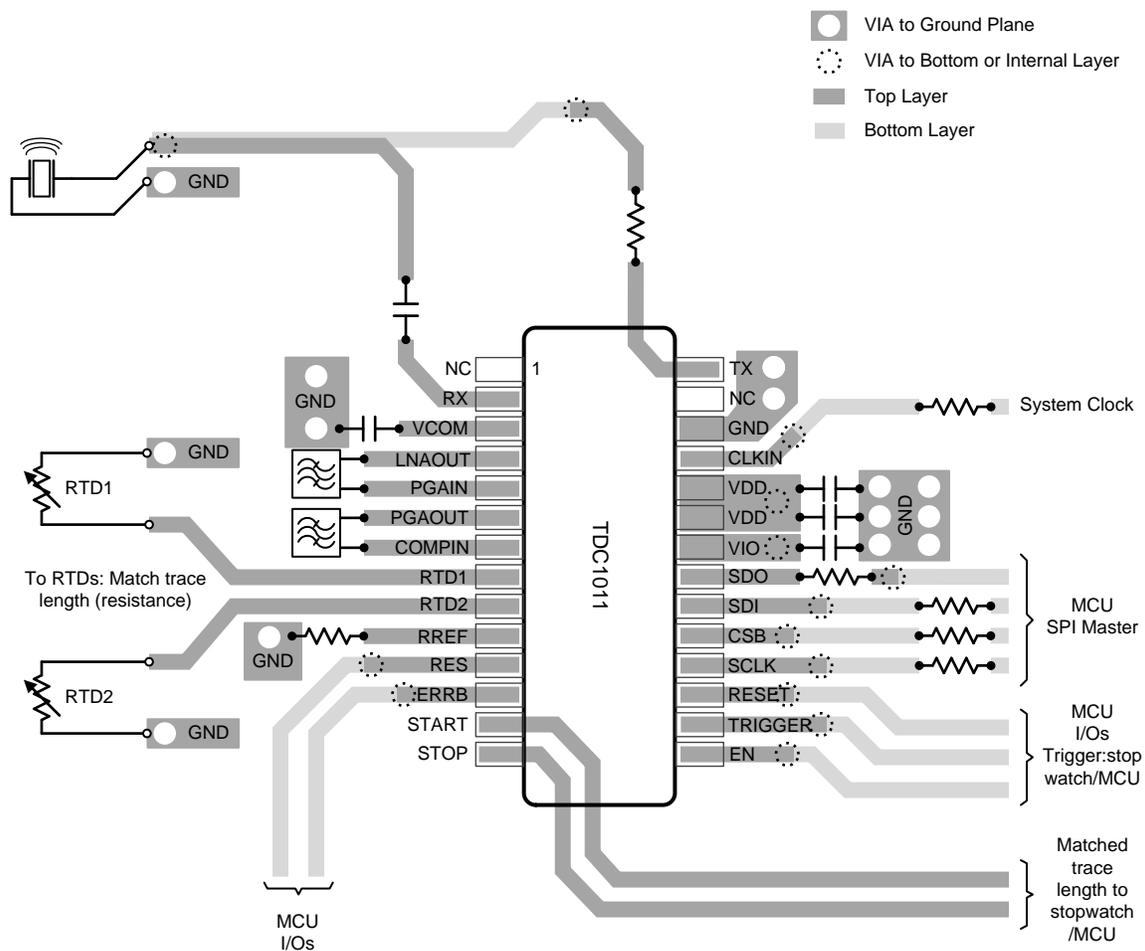


Figure 57. TDC1011 Board Layout (Capacitive Feedback Mode)

12 Device and Documentation Support

12.1 Device Support

12.1.1 Third-Party Products Disclaimer

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12.1.2 Development Support

For development support see the following:

- *Automotive Ultrasonic Fluid Level/Quality Measurement Reference Design*, [TIDA-00322](#)

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](#), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TDC1011PW	PREVIEW	TSSOP	PW	28	48	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	TDC1011PW	
TDC1011PWR	PREVIEW	TSSOP	PW	28	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	TDC1011PW	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TDC1011 :

- Automotive: [TDC1011-Q1](#)

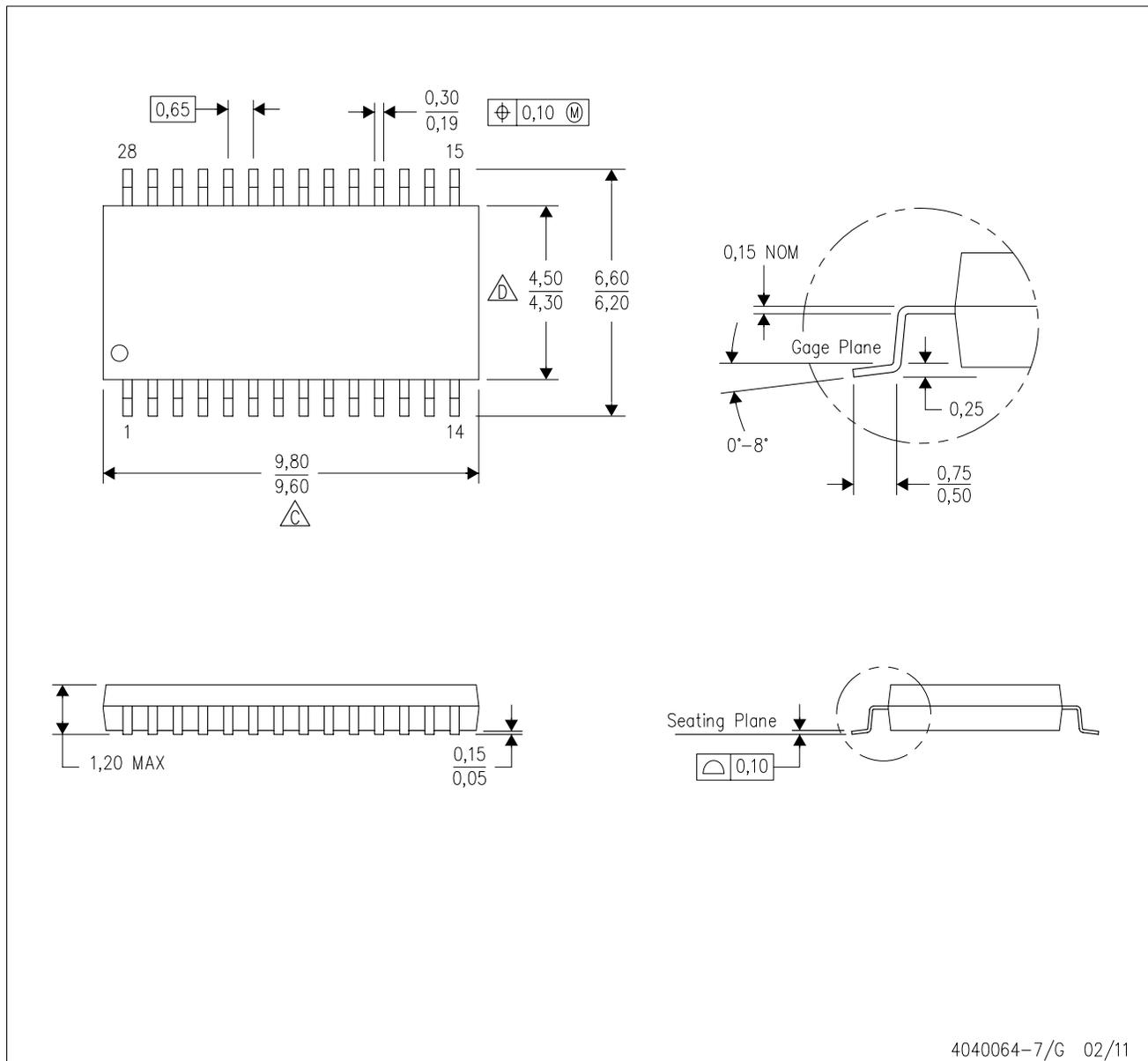
NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

MECHANICAL DATA

PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



4040064-7/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

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